

AD-A058 773

WESTINGHOUSE DEFENSE AND ELECTRONIC SYSTEMS CENTER B--ETC F/G 9/1  
MNOS BORAM MANUFACTURING METHODS AND TECHNOLOGY PROJECT.(U)

JUL 78 J E BREWER

DAAB07-76-C-0048

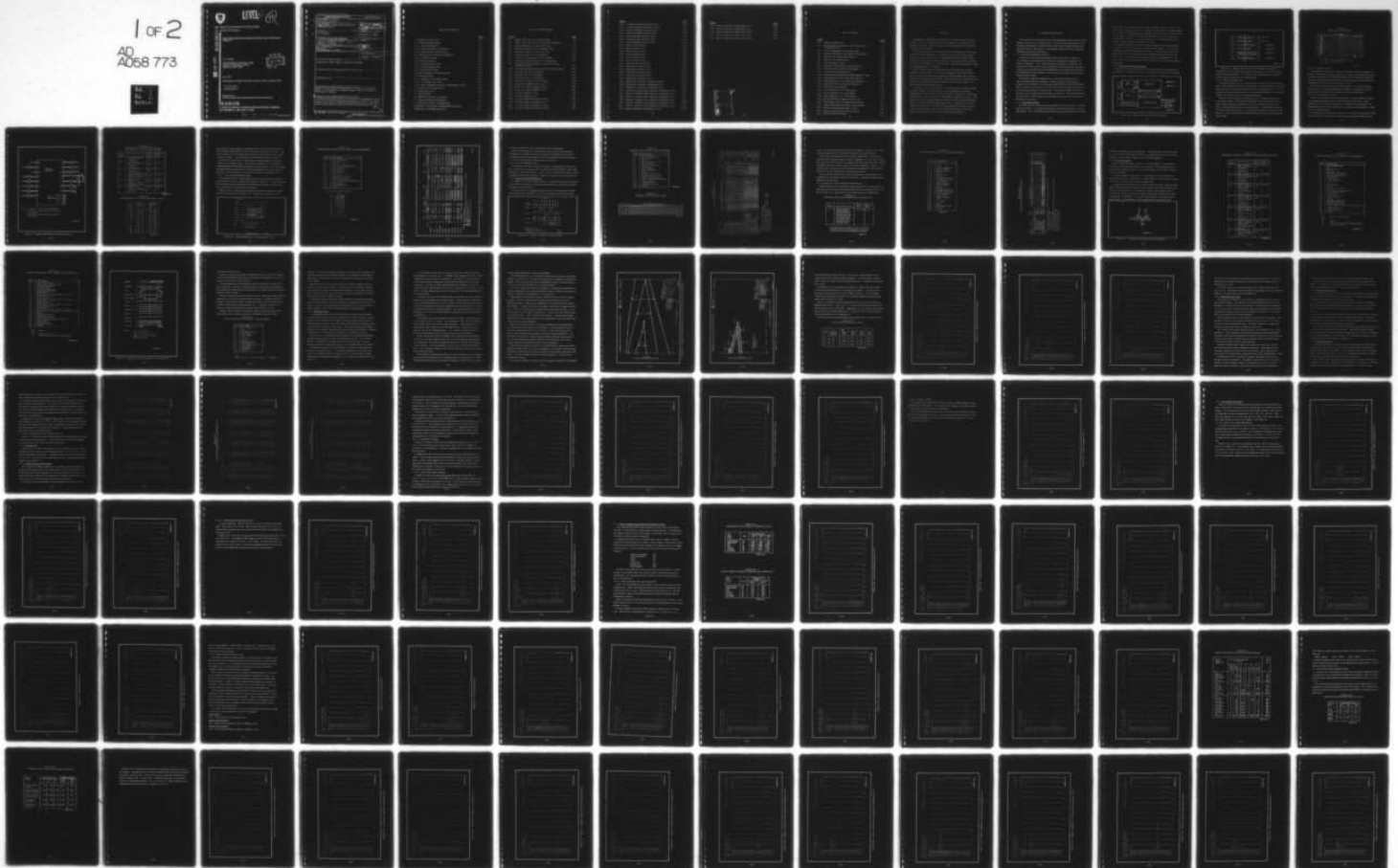
UNCLASSIFIED

78-0481

DELET-TR-76-0048-6

NL

1 OF 2  
AD  
A058 773





**LEVEL**

(11)

SC

AD A058773

DDC FILE COPY

Research and Development Technical Report

DELET-TR-76-0048-6

**MNOS BORAM MANUFACTURING METHODS AND TECHNOLOGY  
PROJECT**

J.E. Brewer

WESTINGHOUSE ELECTRIC CORP  
Systems Development Division  
Baltimore, MD 21203



July 1978

Sixth Quarterly Report for period 1 January 1978 to 31 March 1978

**DISTRIBUTION STATEMENT**

Approved for public release;  
distribution unlimited.

Prepared for:  
US Army Electronics Technology and Devices Laboratory

**ERADCOM**

US ARMY ELECTRONICS RESEARCH AND DEVELOPMENT COMMAND  
FORT MONMOUTH, NEW JERSEY 07703

78 09 06 040 HISA-FM 195-78



SECURITY CLASSIFICATION OF THIS PAGE (When Data Entered)

| 1. REPORT DOCUMENTATION PAGE   |                       | READ INSTRUCTIONS<br>BEFORE COMPLETING FORM  |  |
|--|-----------------------|--|--|
| 1. REPORT NUMBER<br><b>DELET-TR-76-0048-6</b>  | 2. GOVT ACCESSION NO. | 3. RECIPIENT'S CATALOG NUMBER  |  |
| 4. TITLE (and Subtitle)<br><b>MNOS BORAM Manufacturing Methods and Technology Project</b>  |                       | 5. TYPE OF REPORT & PERIOD COVERED<br><b>Quarterly Technical Report no. 6,<br/>1 January 78 to 31 March 78</b> |  |
| 7. AUTHOR(s)<br><b>J. E. Brewer</b>  |                       | 6. PERFORMING ORG. REPORT NUMBER<br><b>78-0481</b>   |  |
| 9. PERFORMING ORGANIZATION NAME AND ADDRESS<br><b>Westinghouse Electric Corporation<br/>Systems Development Division<br/>Baltimore, Maryland</b>   |                       | 8. CONTRACT OR GRANT NUMBER(s)<br><b>DAAB07-76-C-0048</b>  |  |
| 11. CONTROLLING OFFICE NAME AND ADDRESS<br><b>U. S. Army Electronics Technology &amp; Devices Lab<br/>Attn: DELET-ID<br/>ERADCOM<br/>Fort Monmouth, NJ 07703</b>   |                       | 10. PROGRAM ELEMENT PROJECT, TASK AREA & WORK UNIT NUMBERS<br><b>2769758</b>                                   |  |
| 14. MONITORING AGENCY NAME & ADDRESS (if different from Controlling Office)  |                       | 12. REPORT DATE<br><b>July 1978</b>  |  |
|  |                       | 13. NUMBER OF PAGES<br><b>112</b>  |  |
|  |                       | 15. SECURITY CLASS. (of this report)<br><b>UNCLASSIFIED</b>  |  |
|  |                       | 15a. DECLASSIFICATION/DOWNGRADING SCHEDULE   |  |
| 16. DISTRIBUTION STATEMENT (of this Report)<br><b>Approved for public release, distribution unlimited.</b>   |                       |  |  |
| 17. DISTRIBUTION STATEMENT (of the abstract entered in Block 20, if different from Report)   |                       |  |  |
| 18. SUPPLEMENTARY NOTES  |                       |  |  |
| 19. KEY WORDS (Continue on reverse side if necessary and identify by block number)<br><b>MNOS, Metal Nitride Oxide Semiconductor, BORAM, Block Oriented Random, Access Memory, Secondary Storage, Memory, Nonvolatile Semiconductor Memory</b>   |                       |  |  |
| 20. ABSTRACT (Continue on reverse side if necessary and identify by block number)<br><b>A manufacturing methods project has been initiated to establish a pilot production line for metal nitride oxide semiconductor (MNOS) block oriented random access memory (BORAM) multichip hybrid circuits. This report presents some measured characteristics of the BORAM 6002 chip.</b> |                       |  |  |

DD FORM 1 JAN 73 1473

EDITION OF 1 NOV 65 IS OBSOLETE

UNCLASSIFIED

SECURITY CLASSIFICATION OF THIS PAGE (When Data Entered)

iii/iv

405 897

## TABLE OF CONTENTS

|   | <u>Page</u> |
|---|-------------|
| 1. NARRATIVE AND DATA                                   | 1-1         |
| 1.1 Characterization Project                            | 1-1         |
| 1.1.1 Device Description                                | 1-1         |
| 1.1.2 Characterization Test Program                     | 1-2         |
| 1.1.3 Data Collection and Reduction                     | 1-10        |
| 1.2 Functional Test Concepts and Results                | 1-13        |
| 1.2.1 Functional Screen                                 | 1-16        |
| 1.2.2 Retention Screen                                  | 1-22        |
| 1.2.3 Erase Recovery Tests                              | 1-31        |
| 1.2.4 Group Operations Test                             | 1-32        |
| 1.2.5 Read Disturb Tests                                | 1-32        |
| 1.3 Static Parameter Tests and Results                  | 1-33        |
| 1.3.1 Data Summary                                      | 1-33        |
| 1.3.2 Leakage Current Observations                      | 1-33        |
| 1.3.3 I/O Voltage Level Tests                           | 1-45        |
| 1.3.4 Power Dissipation and Static Mode Supply Currents | 1-53        |
| 1.4 Test Structure Observations                         | 1-75        |
| 1.5 Production Activity                                 | 1-93        |
| 2. CONCLUSIONS  | 2-1         |
| 3. PROGRAM FOR NEXT INTERVAL                            | 3-1         |
| 4. PUBLICATIONS AND REPORTS                             | 4-1         |
| 5. IDENTIFICATION OF TECHNICIANS                        | 5-1         |
| APPENDIX A TECHNICAL REQUIREMENT SCS-503                | A-1         |
| APPENDIX B DISTRIBUTION LIST                            | B-1         |

## LIST OF ILLUSTRATIONS

| <u>Figure</u>  | <u>Page</u> |
|--|-------------|
| 1-1 BORAM 6002 Functional Block Diagram                                  | 1-2         |
| 1-2 BORAM 6002 Electrical Test Functional Categories                     | 1-3         |
| 1-3 Signal Assignments for Functional Tests                              | 1-5         |
| 1-4 Operating Sequence for Shift Register Tests                          | 1-7         |
| 1-5 Operating Sequences for Memory Tests                                 | 1-9         |
| 1-6 Detailed Timing for Clocks and Data                                  | 1-10        |
| 1-7 Transistor Test Structure Circuit Diagram                            | 1-16        |
| 1-8 Operating Waveform Sequence for Group Erase                          | 1-20        |
| 1-9 Threshold Voltage Window for Three Write/Erase<br>Voltage Amplitudes | 1-25        |
| 1-10 Threshold Voltage Windows for Reduced Voltage Screen                | 1-26        |
| 1-11 Retention Test 125° C Histogram                                     | 1-28        |
| 1-12 Retention Test 25° C Histogram                                      | 1-29        |
| 1-13 Retention Test -55° C Histogram                                     | 1-30        |
| 1-14 Chip Select Leakage Current at 125° C                               | 1-38        |
| 1-15 Chip Select Leakage Current at 25° C                                | 1-39        |
| 1-16 CMOS Level Input Leakages at 125° C                                 | 1-40        |
| 1-17 CMOS Level Input Leakages at 25° C                                  | 1-41        |
| 1-18 Tristate Leakage at 125° C  | 1-43        |
| 1-19 Tristate Leakage at 25° C   | 1-44        |
| 1-20 I/O Low Voltage Distribution at 125° C                              | 1-46        |
| 1-21 I/O Low Voltage Distribution at 25° C                               | 1-47        |
| 1-22 I/O Low Voltage Distribution at -55° C                              | 1-48        |
| 1-23 I/O High Voltage Distribution at 125° C                             | 1-50        |



| <u>Figure</u>   | <u>Page</u> |
|---|-------------|
| 1-24 I/O High Voltage Distribution at 25°C                | 1-51        |
| 1-25 I/O High Voltage Distribution at -55°C               | 1-52        |
| 1-26 Deselected Standby Current at 125°C                  | 1-56        |
| 1-27 Deselected Standby Current at 25°C                   | 1-57        |
| 1-28 Selected Standby Current at 125°C                    | 1-58        |
| 1-29 Selected Standby Current at 25°C                     | 1-59        |
| 1-30 Selected Standby Current at -55°C                    | 1-60        |
| 1-31 Read Current at 125°C                                | 1-61        |
| 1-32 Read Current at 25°C                                 | 1-62        |
| 1-33 Read Current at -55°C                                | 1-63        |
| 1-34 Write Current at 125°C                               | 1-65        |
| 1-35 Write Current at 25°C                                | 1-66        |
| 1-36 Write Current at -55°C                               | 1-67        |
| 1-37 Chip Clear Current at 125°C                          | 1-68        |
| 1-38 Chip Clear Current at 25°C                           | 1-69        |
| 1-39 Chip Clear Current at -55°C                          | 1-70        |
| 1-40 Group Clear Current at 125°C                         | 1-71        |
| 1-41 Group Clear Current at 25°C                          | 1-72        |
| 1-42 Group Clear Current at -55°C                         | 1-73        |
| 1-43 Nonmemory Transistor Threshold at 125°C              | 1-78        |
| 1-44 Nonmemory Transistor Threshold at 25°C               | 1-79        |
| 1-45 Nonmemory Transistor Threshold at -55°C              | 1-80        |
| 1-46 Memory Transistor High Conduction Threshold at 125°C | 1-81        |
| 1-47 Memory Transistor High Conduction Threshold at 25°C  | 1-82        |
| 1-48 Memory Transistor High Conduction Threshold at -55°C | 1-83        |
| 1-49 Memory Transistor Low Conduction Threshold at 125°C  | 1-84        |
| 1-50 Memory Transistor Low Conduction Threshold at 25°C   | 1-85        |
| 1-51 Memory Transistor Low Conduction Threshold at -55°C  | 1-86        |
| 1-52 Memory Substrate Voltage High at 125°C               | 1-87        |

Figure

- 1-53 Memory Substrate Voltage High at 25°C  
1-54 Memory Substrate Voltage High at -55°C  
1-55 Memory Substrate Voltage Low at 125°C  
1-56 Memory Substrate Voltage Low at 25°C  
1-57 Memory Substrate Voltage Low at -55°C

Page

- 1-88  
1-89  
1-90  
1-91  
1-92

|              |  |
|--------------|--|
| ACCESSION    |  |
| NTIS         | 01 <input checked="" type="checkbox"/> |
| DDC          | 01 28 100 <input type="checkbox"/>     |
| UNANIM       | <input type="checkbox"/>               |
| JUSTIFIC     |  |
| BY           |  |
| DISTRIBUTION |  |
| Dist. A      | CIVIL                                  |
| A            |  |



## LIST OF TABLES

| <u>Table</u>   | <u>Page</u> |
|--|-------------|
| 1-1 Substrate Diode Tests  | 1-4         |
| 1-2 Summary and Description of Test Category No. 2 Functional Screen | 1-6         |
| 1-3 Driver Amplitudes for Functional Tests                           | 1-6         |
| 1-4 Address and Memory Test Logical Flow Sequence                    | 1-8         |
| 1-5 Memory Test Logical Flow Sequence                                | 1-11        |
| 1-6 Memory Test Data Patterns  | 1-11        |
| 1-7 Static Parameter Tests   | 1-12        |
| 1-8 Summary and Description of Retention Test                        | 1-13        |
| 1-9 Retention Screen Logical Flow Sequence                           | 1-14        |
| 1-10 Test Structure Measurements                                     | 1-15        |
| 1-11 Summary and Description of Pulse Response Screen                | 1-17        |
| 1-12 Erase Recovery Test Logical Flow Sequence                       | 1-18        |
| 1-13 Group Operation's Test Logical Flow Sequence                    | 1-19        |
| 1-14 Read Disturb Test Logical Flow Sequence                         | 1-21        |
| 1-15 Retention Screen Statistics                                     | 1-27        |
| 1-16 Static Parameter 125°C Test Results                             | 1-34        |
| 1-17 Static Parameter 25°C Test Results                              | 1-35        |
| 1-18 Static Parameter -55°C Test Results                             | 1-36        |
| 1-19 BORAM 6002 Static Supply Current Levels                         | 1-55        |
| 1-20 Static Supply Current Temperature Sensitivity                   | 1-55        |
| 1-21 BORAM 6002 Operating Modes Time Summary                         | 1-74        |
| 1-22 BORAM 6002 Operating Power Levels                               | 1-75        |
| 1-23 Observed Test Structure Characteristics                         | 1-76        |
| 1-24 BORAM 6002 Yield Growth   | 1-93        |

## PURPOSE

The purpose of manufacturing methods and technology (MM&T) project number 2769758 is to establish a production capability for metal-nitride-oxide semiconductor (MNOS) integrated circuits for block-oriented random-access memory (BORAM).

Military organizations are faced with a difficult hardware problem in the use of modern day computers. A suitable militarized secondary storage technology simply does not exist. Drums and discs cannot stand up under the stress of the ground mobile environment. Military real time programs are forced to be resident in main memory because electromechanical storage access delays cannot be tolerated.

MNOS BORAM holds considerable promise of meeting the military's secondary storage needs. An advanced development Army/Navy MNOS BORAM module has proven that significant volume, weight, power and use flexibility advantages can be achieved. When compared to fixed-head electro-mechanical storage MNOS BORAM offers MTBF's 10 times longer, and access times above 500 times faster.

This MM&T project will establish for the government a source of supply for MNOS BORAM secondary storage. A pilot production line with a demonstrated capacity of 1,875 hybrid circuit per month will be established. Each hybrid circuit will contain 16 MNOS BORAM integrated circuits. This production rate will provide sufficient hybrid circuits to allow fabrication of three 16.8 megabit BORAM modules per month. The hybrid circuits will conform to Electronics Command Technical Requirement SCS503, and the MM&T project will be conducted in accord with Electronics Command Industrial Preparedness Procurement Requirement Number 15.

## 1. NARRATIVE AND DATA

The BORAM 6002 integrated circuit is the development vehicle for the MNOS BORAM manufacturing methods project. During the reporting period the test capability developed for the pilot line was used to learn whether devices meet the specification of this program. This report reviews the status of the test capability and presents test results.

### 1.1 CHARACTERIZATION PROJECT

The devices manufactured during this MM&T project must conform to Army technical requirement SCS-503 which is presented as Appendix A for reference purposes. Prior to beginning pilot production it is necessary to interpret SCS-503 in terms of firm acceptance criteria for electrical screens. In the case of MNOS BORAM, this development was complicated by the need for defining tests which properly evaluate some of the unique characteristics associated with MNOS.

The technical approach employed was to first define specific tests to meet identified screening objectives. Then an automatic equipment test program was developed for the purpose of gathering data on the BORAM 6002 which could verify the validity of the tests and provide distribution information to allow setting suitable screening limits. The quantity of data involved required the use of computer data analysis and reduction. This information base was then used to define automatic test equipment screens for both wafer test and hybrid circuit test.

#### 1.1.1 Device Description

The 6002 chip is a 2048-bit memory intended for use in computer secondary storage systems. It is normally packaged in multichip hybrid form to achieve high density. Use of the MNOS (metal-oxide-nitride-semiconductor) technology

allows nonvolatile information storage and low power operation. The circuit design uses p-channel metal gate transistors on bulk silicon. All bonding pads are 5 mils<sup>2</sup>, and are positioned on opposite side of the die for efficient hybrid circuit layout. A glass overcoat guards against scratches due to handling. All inputs have protective voltage limiting devices to avoid damage by static charge. The die measures 99 mils by 128 mils.

As shown in figure 1-1 the BORAM 6002 contains a fully decoded 64-word by 32-bit RAM and 32-bit dynamic two-phase shift register. All I/O are accomplished serially through the shift register. Parallel bidirectional data transfer between the RAM and the shift register takes place via an internal 32-bit latch. The RAM and shift register can operate independently. Data stored in the latch may be written into the RAM while new data is shifted into the register.

#### 1.1.2 Characterization Test Program

Characterization of BORAM 6002 devices was aided by a Macrodata 501 test program. As shown in figure 1-2 six categories of tests were employed.

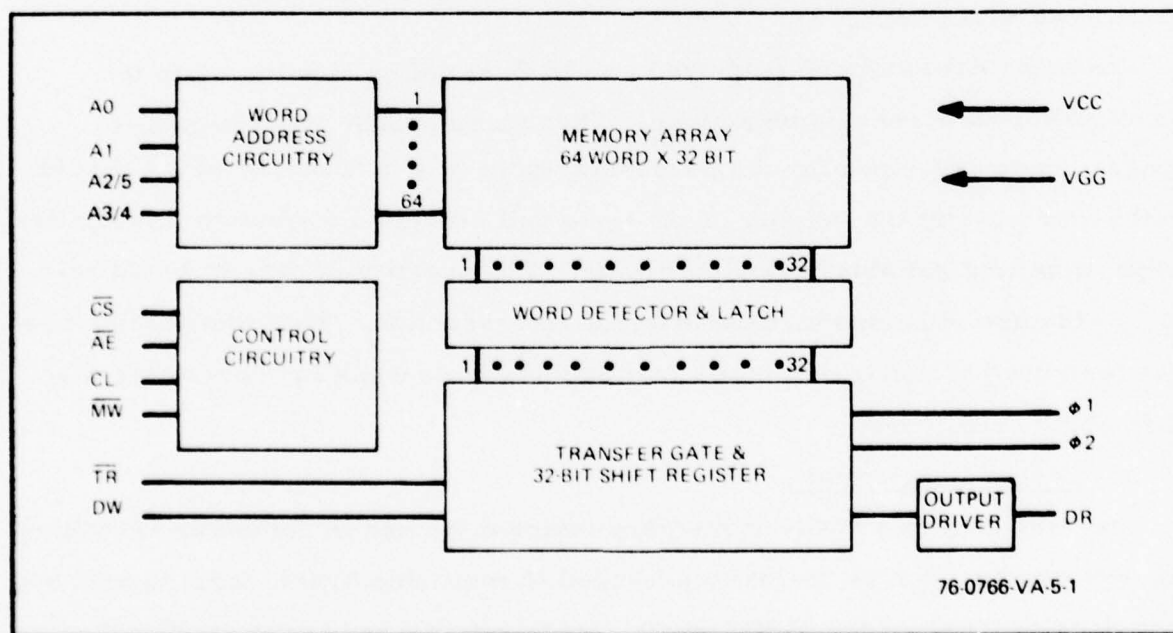


Figure 1-1. BORAM 6002 Functional Block Diagram



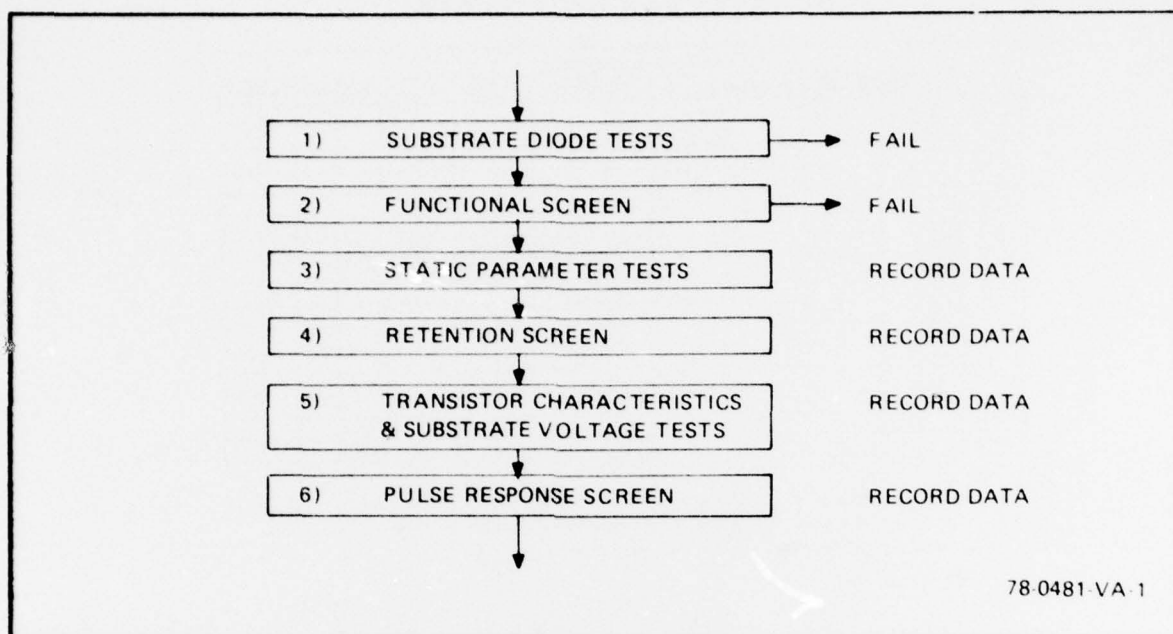


Figure 1-2. BORAM 6002 Electrical Test Functional Categories

The purpose of the program was to gather information on the nature of parts suitable for use in systems. The first two test categories were included to exclude nonfunctional parts from the data base.

#### 1.1.2.1 Substrate Diode Tests

The substrate diode tests are relevant when the product is tested in wafer form. Observation of the forward voltage drop of the substrate diode associated with input terminals provides positive evidence of good probe contact. In rare cases this test can also be an indicator of process problems such as inadequate etching, poor ohmic contact, or improper diffusions.

Table 1-1 and associated foot notes define the 16 substrate diode tests. Every input terminal to the BORAM chip has an associated substrate diode. Under normal operating conditions where VCC is maintained as the most positive chip voltage this diode is reverse biased. A similar situation exists for the on-chip test structures. In this case the reference node is SUB rather than VCC. The GT terminal is isolated and does not have an associated substrate diode.



TABLE 1-1  
SUBSTRATE DIODE TESTS

| Test Number | Device Terminal Conditions <sup>1</sup> |    |     |    |      |      |    |    |    |    |    |    |    |    |    |     |    |
|-------------|---|----|-----|----|------|------|----|----|----|----|----|----|----|----|----|-----|----|
|             | VCC                                     | TR | VGG | CS | A2/5 | A3/4 | A0 | A1 | AE | AW | CL | OR | DW | Q2 | Q1 | SUB | MD |
| 1-1         | GND                                     | 1  |     |    |      |      |    |    |    |    |    |    |    |    |    |     |    |
| 1-2         | GND                                     |    |     |    |      |      | 1  |    |    |    |    |    |    |    |    |     |    |
| 1-3         | GND                                     |    |     |    |      | 1    |    |    |    |    |    |    |    |    |    |     |    |
| 1-4         | GND                                     |    |     |    |      |      |    |    |    |    | 1  |    |    |    |    |     |    |
| 1-5         | GND                                     |    |     |    |      |      |    | 1  |    |    |    |    |    |    |    |     |    |
| 1-6         | GND                                     |    |     | 1  |      |      |    |    |    |    |    |    |    |    |    |     |    |
| 1-7         | GND                                     |    |     |    |      |      |    |    |    |    |    |    |    | 1  |    |     |    |
| 1-8         | GND                                     |    |     |    |      |      |    |    |    |    |    |    | 1  |    |    |     |    |
| 1-9         | GND                                     |    | 1   |    |      |      |    |    |    |    |    |    |    |    |    |     |    |
| 1-10        | GND                                     |    |     |    | 1    |      |    |    |    |    |    |    |    |    |    |     |    |
| 1-11        | GND                                     |    |     |    |      |      |    |    | 1  |    |    |    |    |    |    |     |    |
| 1-12        | GND                                     |    |     |    |      |      |    |    |    | 1  |    |    |    |    |    |     |    |
| 1-13        | GND                                     |    |     |    |      |      |    |    |    |    |    |    |    |    | 1  |     |    |
| 1-14        | GND                                     |    |     |    |      |      |    |    |    |    |    | 1  |    |    |    |     |    |
| 1-15        |   |    |     |    |      |      |    |    |    |    |    |    |    |    |    | GND | 1  |
| 1-16        |   |    |     |    |      |      |    |    |    |    |    |    |    |    |    | GND | 1  |

Notes

1. This is the **node** under test. Force 0.2 milliamperes into the node and measure the resulting voltage from the node to ground. Accept voltage readings from +0.3 volts up to 1.0 volts.
2. The GT terminal does not have an associated substrate diode.
3. Terminals not labeled are open circuited.

78 0286 TA 01

### 1.1.2.2 Functional Screen

The purpose of the functional screen is to quickly eliminate nonoperative die from consideration for characterization. Table 1-2 provides an overview of the six tests which are performed at nominal device operating conditions. This table references additional figures and tables which fully define the test conditions (figures 1-3 to 1-6 and tables 1-3 to 1-6).

The first three tests exercise the shift register. The next test verifies that all memory cells can be properly addressed for writing and reading. The final two tests exercise all memory cells in both data states.

### 1.1.2.3 Static Parameter Tests

Table 1-7 defines the static parameter tests. This test sequence exhaustively examines the device under test for leakage current levels, signal threshold values, output drive capability and supply current demand. The significance of these tests is examined in more detail in paragraph 1.3 below.

### 1.1.2.4 Retention Screen

The retention characteristics of a device are not directly measurable within the milliseconds of time that are practical for an automatic equipment test.

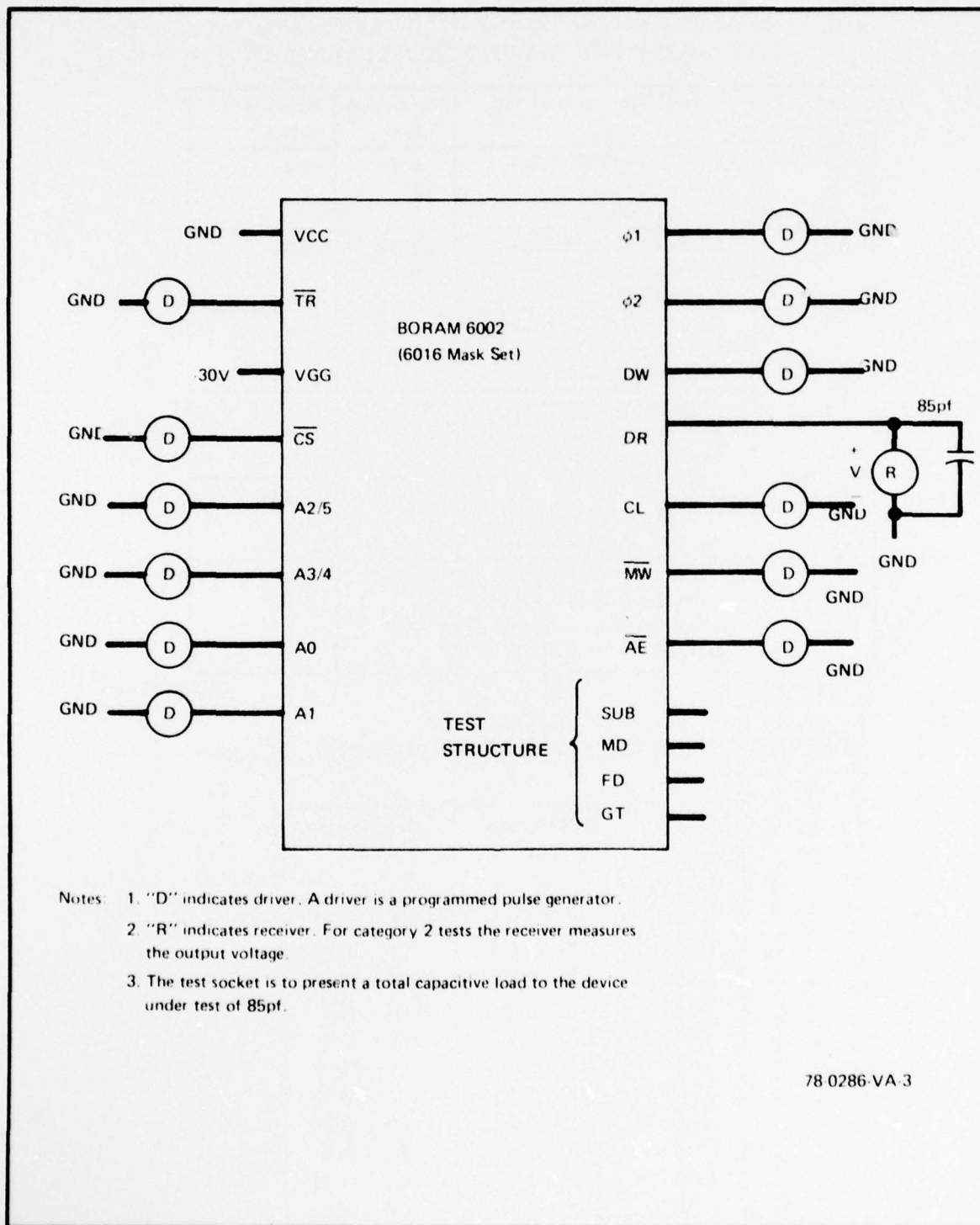


Figure 1-3. Signal Assignments for Functional Tests

TABLE 1-2  
SUMMARY AND DESCRIPTION OF TEST  
CATEGORY NO. 2 FUNCTIONAL SCREEN

| Test Number | General Description of Test  | Referenced Figures | Referenced Tables |
|-------------|--|--------------------|-------------------|
| 2-1         | SHIFT REGISTER TEST<br>1 MHz data rate<br>zero data pattern                                | 1-3, 1-4,<br>1-6   | 1-3               |
| 2-2         | SHIFT REGISTER TEST<br>1 MHz data rate<br>one data pattern                                 | 1-3, 1-4,<br>1-6   | 1-3               |
| 2-3         | SHIFT REGISTER TEST<br>1 MHz data rate<br>zero-one data pattern                            | 1-3, 1-4,<br>1-6   | 1-3               |
| 2-4         | ADDRESS & MEMORY TEST<br>1000μsec erase, 200μsec write<br>diagonal data pattern            | 1-3, 1-5,<br>1-6   | 1-3, 1-4          |
| 2-5         | MEMORY TEST<br>1000μsec erase, 200μsec write<br>checkerboard data pattern                  | 1-3, 1-5,<br>1-6   | 1-3, 1-5,<br>1-6  |
| 2-6         | MEMORY TEST<br>1000μsec erase, 200μsec write<br>complementary checkerboard<br>data pattern | 1-3, 1-5,<br>1-6   | 1-3, 1-5,<br>1-6  |

78-0286-TA-2-1

TABLE 1-3  
DRIVER AMPLITUDES FOR FUNCTIONAL TESTS

| Signal Symbol   | Most Positive Amplitude Volts | Most Negative Amplitude Volts |
|-----------------|-------------------------------|-------------------------------|
| $\overline{TR}$ | VCC - 2.0                     | VCC - 10.5                    |
| $\overline{CS}$ | VCC - 2.0                     | VCC - 34.65                   |
| A2/5            | VCC - 2.0                     | VCC - 10.5                    |
| A3/4            | VCC - 2.0                     | VCC - 10.5                    |
| A0              | VCC - 2.0                     | VCC - 10.5                    |
| A1              | VCC - 2.0                     | VCC - 10.5                    |
| φ1              | VCC - 2.0                     | VCC - 14.25                   |
| φ2              | VCC - 2.0                     | VCC - 14.25                   |
| DW              | VCC - 2.0                     | VCC - 10.5                    |
| CL              | VCC - 2.0                     | VCC - 14.25                   |
| $\overline{MW}$ | VCC - 2.0                     | VCC - 10.5                    |
| $\overline{AE}$ | VCC - 2.0                     | VCC - 10.5                    |

78-0286-T-4

The objective of the retention oriented test in the characterization program was to isolate chips which are likely to have poor nonvolatile retention. The test simulates end-of-retention conditions by writing the memory cells using a reduced voltage. Test conditions are documented in tables 1-8 and 1-9.

Note that erase and read are performed at nominal supply voltages and nominal control signal timing. This avoids confusion of circuit voltage and timing operating limitations with possible retention defects. The write voltage is progressively reduced until the threshold voltage window can no longer be detected. The interpretation of this test is discussed in paragraph 1.2.2.

#### 1.1.2.5 Test Structure Measurements

The BORAM 6002 die contains some device structures which are not part of the functional memory configuration defined in figure 1-1. These structures were provided to allow measurement of fundamental process characteristics, and include several capacitors and transistors.

Probe test is a convenient point to gather statistically significant amounts of data without incurring excessive cost. These test structures are not

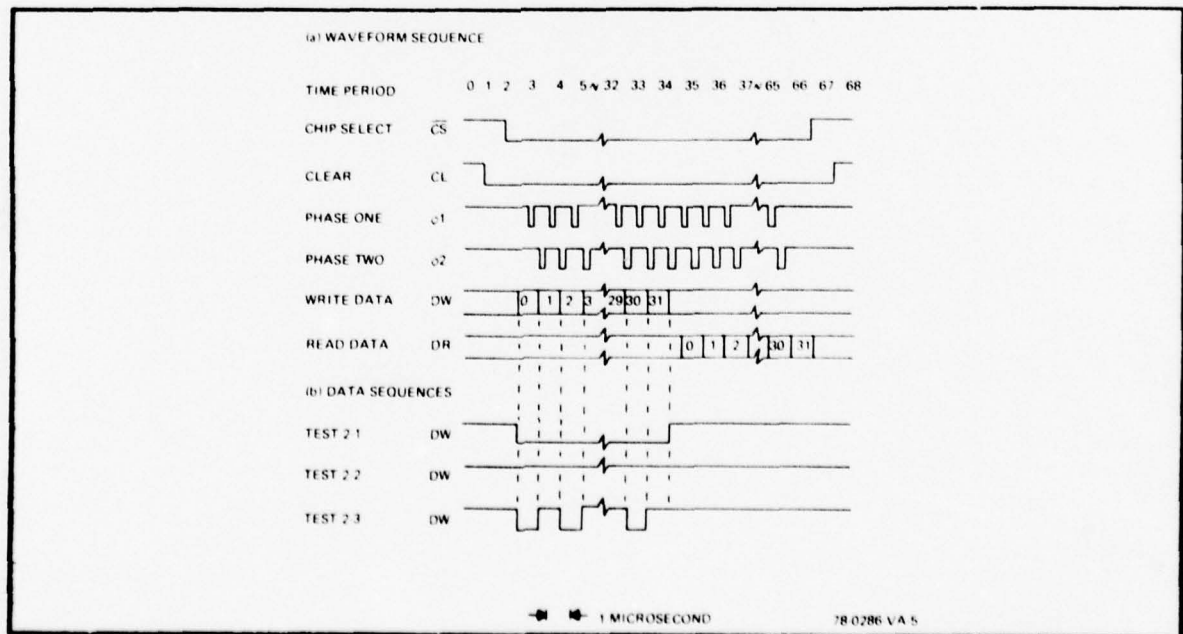


Figure 1-4. Operating Sequence for Shift Register Tests



TABLE 1-4  
ADDRESS AND MEMORY TEST LOGICAL FLOW SEQUENCE

| Step | Logical Operation                                   |
|------|---|
| 1    | Setup CL and $\overline{CS}$ per Fig. 5a            |
| 2    | Block Erase per Fig. 5b                             |
| 3    | Address = 0   |
| 4    | Setup Address Lines per Fig. 5c                     |
| 5    | Data = Function (Address) per Note Below            |
| 6    | Load Shift Register per Fig. 5d                     |
| 7    | Write Data per Fig. 5e                              |
| 8    | Address = Address + 1                               |
| 9    | If (Address < 64) then 4                            |
| 10   | Address = 0   |
| 11   | Setup Address Lines per Fig. 5c                     |
| 12   | Read Data to Latch per Fig. 5f                      |
| 13   | Empty Shift Register per Fig. 5g                    |
| 14   | If (Data $\neq$ Function (Address)) then BIN and 18 |
| 15   | Address = Address + 1                               |
| 16   | If (Address < 64) then 11                           |
| 17   | Reset CS and CL per Fig. 5h                         |
| 18   | End Routine   |

Note: Diagonal Data Pattern per Figure below:

| Rows | Columns |   |   |    |    |   |
|------|---------|---|---|----|----|---|
|      | 0       | 1 | ~ | 30 | 31 |   |
| 0    | 0       | 0 | 0 | 0  | 0  | 1 |
| 1    | 0       | 0 | 0 | 0  | 1  | 0 |
| 5    | 0       | 0 | 0 | 1  | 0  | 0 |
|      | 0       | 0 | 1 | 0  | 0  | 0 |
| 30   | 0       | 1 | 0 | 0  | 0  | 0 |
| 31   | 1       | 0 | 0 | 0  | 0  | 0 |
| 32   | 1       | 1 | 1 | 1  | 1  | 0 |
| 33   | 1       | 1 | 1 | 1  | 0  | 1 |
| 5    | 1       | 1 | 1 | 0  | 1  | 1 |
|      | 1       | 1 | 0 | 1  | 1  | 1 |
| 62   | 1       | 0 | 1 | 1  | 1  | 1 |
| 63   | 0       | 1 | 1 | 1  | 1  | 1 |

78-0286 TA-7



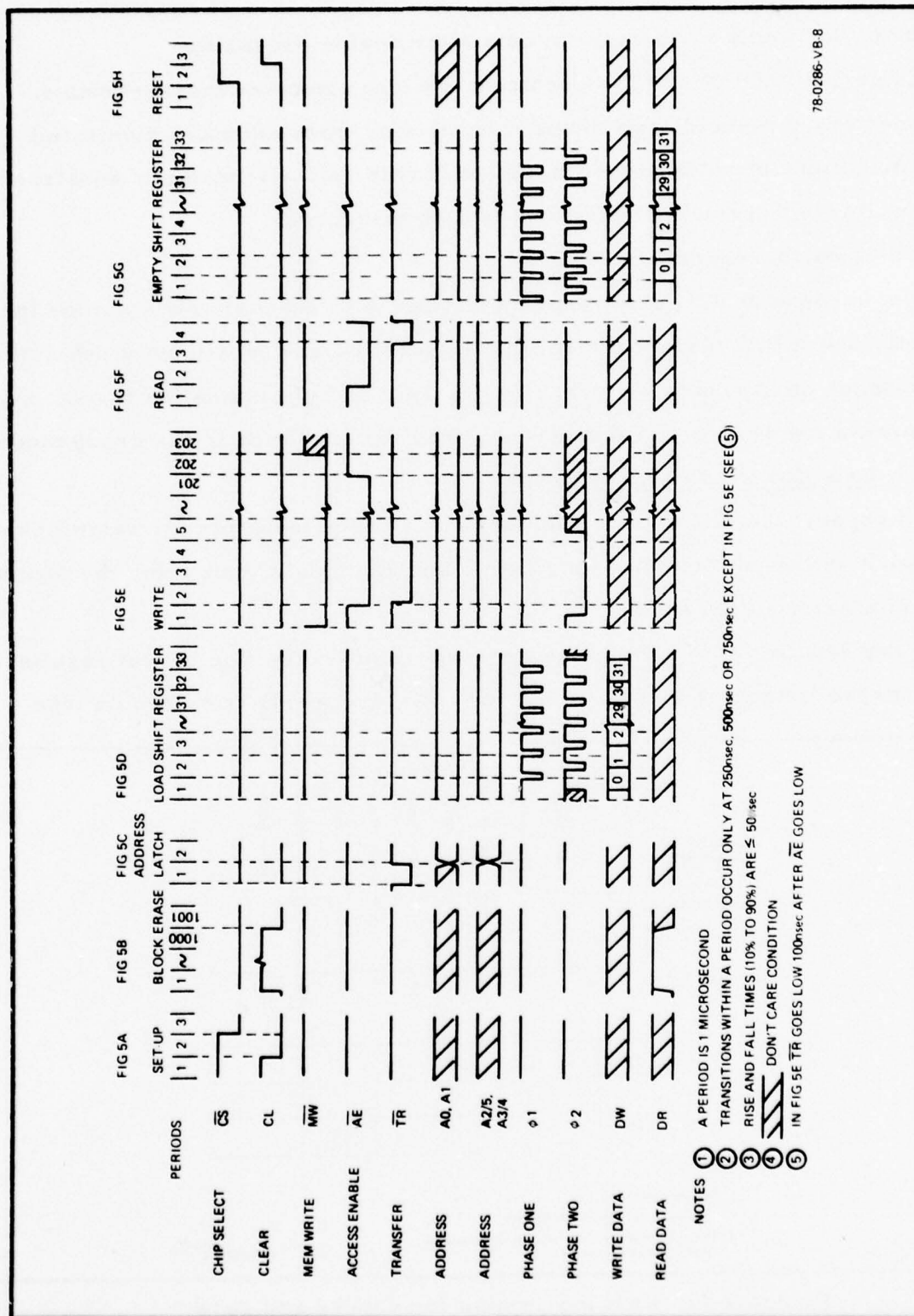


Figure 1-5. Operating Sequences for Memory Tests

normally available for measurements after device packaging.

Table 1-10 and figure 1-7 document the test structure measurements. Nonmemory threshold, and memory transistor thresholds are monitored. The magnitude of voltage present on the N type epitaxial memory substrate for two circuit operating conditions is also measured.

#### 1.1.2.6 Pulse Response Screen

The purpose of the pulse response screen is to exhaustively examine the part to insure that it can perform in all operating modes without a detracting dependence on past data history. Tables 1-11 to 1-14 define the tests. Figure 8 presents the waveform sequence required for operation in the group mode.

#### 1.1.3 Data Collection and Reduction

To support the characterization project a computer program was prepared to facilitate the collection, organization and analysis of data from the Macro-data characterization tests.

A key feature of this computer program is the collection of test results on a magnetic tape cartridge. Data for individual parts is stored on tape

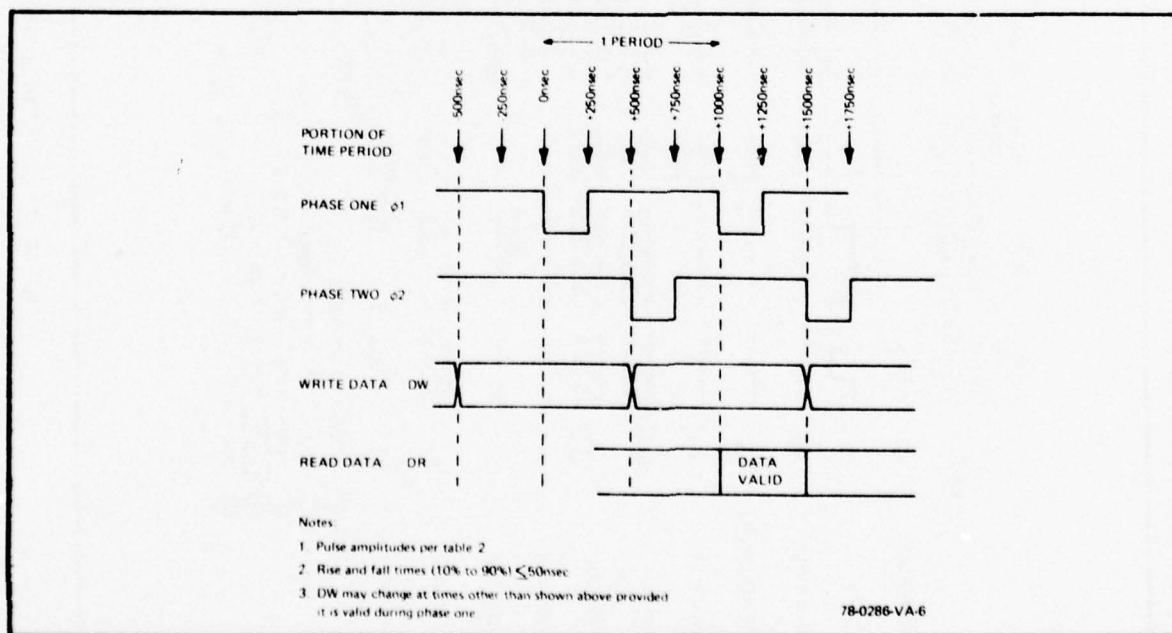


Figure 1-6. Detailed Timing for Clocks and Data

TABLE 1-5  
MEMORY TEST LOGICAL FLOW SEQUENCE

| Step | Logical Operation                              |
|------|--|
| 1    | Setup CL and $\overline{CS}$ per Fig. 5a       |
| 2    | Block Erase per Fig. 5b                        |
| 3    | Address = 0                                    |
| 4    | Setup Address Lines per Fig. 5c                |
| 5    | Data = (per Table 6)                           |
| 6    | Load Shift Register per Fig. 5d                |
| 7    | Write Data per Fig. 5e                         |
| 8    | Address = Address + 1                          |
| 9    | If (Address $< 64$ ) then 4                    |
| 10   | Address = 0                                    |
| 11   | Setup Address Lines per Fig. 5c                |
| 12   | Read Data to Latch per Fig. 5f                 |
| 13   | Empty Shift Register per Fig. 5g               |
| 14   | If (Data $\neq$ (per Table 6)) then BIN and 18 |
| 15   | Address = Address + 1                          |
| 16   | If (Address $< 64$ ) then 11                   |
| 17   | Reset $\overline{CS}$ and CL per Fig. 5h       |
| 18   | End Routine                                    |

78-0286-TA-9

TABLE 1-6  
MEMORY TEST DATA PATTERNS

| Test Number | Row Address | Data Pattern Required In Shift Register |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |    |   |   |   |   |   |   |   |   |   |   |   |   |
|-------------|-------------|---|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|----|---|---|---|---|---|---|---|---|---|---|---|---|
|             |             | 31                                      | 30 | 29 | 28 | 27 | 26 | 25 | 24 | 23 | 22 | 21 | 20 | 19 | 18 | 17 | 16 | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |   |   |
| 2-5         | Even        | 1                                       | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 |
| 2-5         | Odd         | 0                                       | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 |
| 2-6         | Even        | 0                                       | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 |
| 2-6         | Odd         | 1                                       | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 | 1 | 0 |

78-0286 TA 10

TABLE 1-7  
STATIC PARAMETER TESTS

| Test Number | Test Description                 | Device Terminal Conditions 6 |      |     |        |      |      |      |      |      |      |      |    |        | Terminal Under Test | 25°C Test Limits |      |      |      |       |
|-------------|----------------------------------|------------------------------|------|-----|--------|------|------|------|------|------|------|------|----|--------|---------------------|------------------|------|------|------|-------|
|             |                                  | VCC                          | TR   | VGG | CS     | A2 5 | A3 4 | A0   | A1   | AE   | MW   | CL   | DR | DW     |                     | Q2               | Q1   | Min  | Max  | Units |
| 3-1         | Input Leakage                    | 1                            |      |     | -37.5V |      |      |      |      |      |      |      |    |        |                     |                  | CS   |      | 20   | μA    |
| 3-2         | Input Leakage                    | +20V                         | 2    | 10V | +20V   | +20V | +20V | +20V | +20V | +20V | +20V | +5V  |    | -20V   | +20V                | +20V             | TR   |      | 10   | μA    |
| 3-3         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | 2    | +20V | +20V | +20V | +5V  |    | -20V   | +20V                | +20V             | A0   |      | 10   | μA    |
| 3-4         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | 2    | +20V | +20V | +20V | +20V | +5V  |    | -20V   | +20V                | +20V             | A3 4 |      | 10   | μA    |
| 3-5         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | 2    | +20V | +20V | +5V  |    | -20V   | +20V                | +20V             | A1   |      | 10   | μA    |
| 3-6         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | +20V | +20V | +20V | +5V  |    | -20V   | 2                   | +20V             | Q2   |      | 10   | μA    |
| 3-7         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | +20V | +20V | +20V | +5V  |    | 2      | +20V                | +20V             | DW   |      | 10   | μA    |
| 3-8         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | 2    | +20V | +20V | +20V | +20V | +20V | +5V  |    | -20V   | +20V                | +20V             | A2 5 |      | 10   | μA    |
| 3-9         | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | +20V | 2    | +20V | +5V  |    | -20V   | +20V                | +20V             | AE   |      | 10   | μA    |
| 3-10        | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | +20V | +20V | 2    | +5V  |    | -20V   | +20V                | +20V             | MW   |      | 10   | μA    |
| 3-11        | Input Leakage                    | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | +20V | +20V | +20V | +5V  |    | -20V   | +20V                | 2                | Q1   |      | 10   | μA    |
| 3-12        | Tristate Leakage                 | +20V                         | +20V | 10V | +20V   | +20V | +20V | +20V | +20V | +20V | +20V | +5V  | 2  | -20V   | +20V                | +20V             | DR   |      | 10   | μA    |
| 3-13        | Input & Output Low Voltage Test  | GND                          | GND  | 30V | 35V    | GND  | GND  | GND  | GND  | GND  | GND  | -15V | 3  | 10.25V | 14V                 | 14V              | DR   | 10.5 |      | Volts |
| 3-14        | Input & Output High Voltage Test | GND                          | GND  | 30V | 35V    | GND  | GND  | GND  | GND  | GND  | GND  | -15V | 4  | -1.75V | -14V                | 14V              | DR   |      | 4.5  | Volts |
| 3-15        | Supply Current Deslected Standby | 5                            | GND  | 30V | GND    | GND  | GND  | GND  | GND  | GND  | GND  | -15V |    | GND    | GND                 | GND              | VCC  |      | 1000 | μA    |
| 3-16        | Supply Current Selected Standby  | 5                            | GND  | 33V | 33V    | GND  | GND  | GND  | GND  | GND  | GND  | -15V |    | GND    | GND                 | GND              | VCC  | 7.0  | 15.0 | mA    |
| 3-17        | Supply Current Read              | 5                            | GND  | 33V | 33V    | GND  | GND  | GND  | GND  | -15V | GND  | -15V |    | GND    | GND                 | GND              | VCC  | 11.0 | 37.0 | mA    |
| 3-18        | Supply Current Write             | 5                            | GND  | 33V | 33V    | GND  | GND  | GND  | GND  | 15V  | 15V  | -15V |    | GND    | GND                 | GND              | VCC  | 10.0 | 32.0 | mA    |
| 3-19        | Supply Current Chip Clear        | 5                            | GND  | 33V | 33V    | GND  | GND  | GND  | GND  | GND  | GND  | GND  |    | GND    | GND                 | GND              | VCC  | 7.0  | 15.0 | mA    |
| 3-20        | Supply Current Group Clear       | 5                            | GND  | 33V | 33V    | GND  | GND  | GND  | GND  | -15V | 15V  | GND  |    | GND    | GND                 | GND              | VCC  | 8.0  | 18.0 | mA    |

Notes

- 1 Measure the current flow from GND into VCC
- 2 Measure the current flow out of this node to GND
- 3 Force 5 milliamperes into DR and measure the voltage from DR to GND
- 4 Force 5 milliamperes out of DR and measure the voltage from DR to GND
- 5 Measure the current from GND into VCC
- 6 Terminals not labeled are open circuited



files, and can be automatically searched and updated. Extensive user interaction features promote checking and comparison of stored results.

Two primary data summary features were established. The first was a statistical data summary report for specific samples. In this case the computer searches the tape files for all parts which meet some selection criteria. A possible selection criteria might be "all parts measured at +125°C." The program then computes means and measures of dispersion, and prints the results for the 26 variables data characterization tests.

The second data summary feature of the program is the preparation of histograms for individual characterization tests. Examples of these reports appear in the text below.

## 1.2 FUNCTIONAL TEST CONCEPTS AND RESULTS

MNOS BORAM devices necessarily have a great deal in common with conventional semiconductor memories and share similar problems in test. On the other hand, the nonvolatility and the physical nature of MNOS does

TABLE 1-8  
SUMMARY AND DESCRIPTION OF RETENTION TEST

| Test Number | General Description of Test  | Referenced Figures | Referenced Tables |
|-------------|--|--------------------|-------------------|
| 4-1         | RETENTION SCREEN<br>1000 $\mu$ sec erase, 200 $\mu$ sec write all zero and all one data patterns VGG= -30 V for erase and read VGG for write is reduced by 0.5V increments until the device under test fails. The last pass voltage is recorded. | 1-3*, 1-5, 1-6,    | 1-3, 1-9          |

- \* Provision must be made for varying VGG. In figure 1-3 VGG is shown as -30 volts. At the option of the test programmer a driver may be assigned to this terminal or the supply voltage may be incremented.

78-0481-TA-2



TABLE 1-9  
RETENTION SCREEN LOGICAL FLOW SEQUENCE

| Step | Logical Operation                         |
|------|---|
| 1    | $J = -30$                                 |
| 2    | $K = 0$                                   |
| 3    | Setup CL and $\overline{CS}$ per fig. 5a. |
| 4    | Set VGG = -30 volts                       |
| 5    | Block erase per fig. 5b                   |
| 6    | Data = K                                  |
| 7    | Set VGG = J volts                         |
| 8    | Address = 0                               |
| 9    | Setup address lines per fig. 5c           |
| 10   | Load shift register per fig. 5d           |
| 11   | Write data per fig. 5e                    |
| 12   | Address = address + 1                     |
| 13   | If (address < 64) then 9                  |
| 14   | Set VGG = -30 volts                       |
| 15   | Address = 0                               |
| 16   | Setup address lines per fig. 5c           |
| 17   | Read data to latch per fig. 5f            |
| 18   | Empty shift register per fig. 5g          |
| 19   | If (data $\neq$ K) then 26                |
| 20   | Address = address + 1                     |
| 21   | If (address < 64) then 16                 |
| 22   | $K = \overline{K}$                        |
| 23   | If (K = 1) then 4                         |
| 24   | $J = J + 0.5$                             |
| 25   | Go to 4                                   |
| 26   | Reset $\overline{CS}$ and CL per fig. 5h  |
| 27   | Print J = 0.5                             |
| 28   | End Routine                               |

78-0481-TA-3

TABLE 1-10  
TEST STRUCTURE MEASUREMENTS

| Test Number | Description                              | Phase of test         | Device Terminal Conditions |     |     |     |      |      |     |     |     |     |     |     |     |          |     |    |    |    |  |
|-------------|--|-----------------------|----------------------------|-----|-----|-----|------|------|-----|-----|-----|-----|-----|-----|-----|----------|-----|----|----|----|--|
|             |  |                       | VCC                        | TR  | VGG | CS  | A2/5 | A3/4 | A0  | A1  | AE  | WW  | CL  | DR  | DW  | $\phi$ 1 | SUB | MD | FD | GT |  |
| 5 1         | Nonmemory threshold voltage              | measurement           |                            |     |     |     |      |      |     |     |     |     |     |     |     |          | GND |    | 1  | 1  |  |
| 5 2         | Memory high conduction threshold voltage | set up<br>measurement |                            |     |     |     |      |      |     |     |     |     |     |     |     |          | GND |    |    | 2  |  |
| 5 3         | Memory low conduction threshold voltage  | set up                |                            |     |     |     |      |      |     |     |     |     |     |     |     |          | GND | 3  |    | 3  |  |
|             |  | measurement           |                            |     |     |     |      |      |     |     |     |     |     |     |     |          | GND |    |    | 4  |  |
| 5 4         | Substrate voltage high                   | measurement           | GND                        | GND | 30V | 35V | GND  | GND  | GND | 15V | GND | 15V | GND | GND | GND | GND      | GND | 5  |    |    |  |
| 5 5         | Substrate voltage low                    | measurement           | GND                        | GND | 30V | 35V | GND  | GND  | GND | GND | GND | GND | GND | GND | GND | GND      | GND | 5  |    |    |  |

Notes:

1. Tie the fixed drain (FD) and gate (GT) terminals together. Force 10 microamps out of the node and measure the voltage from the node to ground (GND)
2. Pulse GT to +25 volts for 1 millisecond
3. Tie the memory drain (MD) and gate (GT) terminals together. Force 10 microamps out of the node and measure the voltage from the node to ground (GND)
4. Pulse GT to -25 volts for 200 microseconds
5. Measure the voltage from SUB to (GND)

78-0286 TA-14

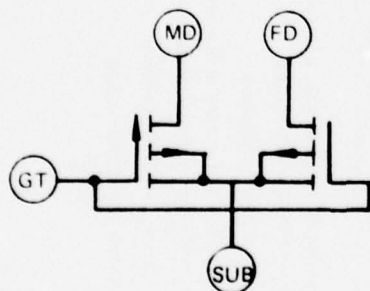
introduce some new tests considerations. This discussion reviews the rational for each of the functionally oriented tests employed in the characterization program, and the results obtained from a sample population.

### 1.2.1 Functional Screen

Before considering a part suitable for characterization it is screened to certify that it does operate properly as a memory. The test approach first verifies shift register operation, and then continues to confirm that the RAM performs adequately.

The shift register is operated at a 1 MHz rate into a rated load with all input signals at worst rated values. The data pattern is varied from all zeros to all ones, and then to alternating zeros and ones.

The operation of the device as a BORAM is then examined. Address unique data (a diagonal pattern) is shifted into the register and written into the RAM. This is accomplished at a 1 MHz shift rate with all input signals at worst rated values. Rated erase time of 1000 microseconds and write time of 200 microseconds is employed. The entire chip is written, and then the entire chip is read. This procedure is then repeated using checkerboard and



78-0286-VA-15

Figure 1-7. Transistor Test Structure Circuit Diagram

TABLE 1-11  
SUMMARY AND DESCRIPTION OF PULSE RESPONSE SCREEN

| Test Number | General Description of Test   | Referenced Figures    | Referenced Tables |
|-------------|---|-----------------------|-------------------|
| 6-1         | ERASE RECOVERY TEST<br>1000 $\mu$ sec erase, 200 $\mu$ sec write<br>zero data pattern<br>erase write 100 times<br>one data pattern<br>erase write 1 time, read  | 1-3, 1-5,<br>1-6      | 1-3, 1-12         |
| 6-2         | ERASE RECOVERY TEST<br>1000 $\mu$ sec erase, 200 $\mu$ sec write<br>one data pattern<br>erase write 100 times<br>zero data pattern<br>erase write 1 time, read  | 1-3, 1-5,<br>1-6      | 1-3, 1-12         |
| 6-3         | ERASE RECOVERY TEST<br>1000 $\mu$ sec erase, 200 $\mu$ sec write<br>checkerboard pattern<br>erase write 100 times<br>complement checkerboard<br>pattern<br>erase write 1 time, read                   | 1-3, 1-5,<br>1-6      | 1-3, 1-12         |
| 6-4         | ERASE RECOVERY TEST<br>1000 $\mu$ sec erase, 200 $\mu$ sec write<br>complement checkerboard<br>pattern<br>erase write 100 times<br>checkerboard pattern<br>erase write 1 time, read                   | 1-3, 1-5,<br>1-6      | 1-3, 1-12         |
| 6-5         | GROUP OPERATION TEST<br>1000 $\mu$ sec erase, 200 $\mu$ sec write<br>complement checkerboard<br>pattern<br>begin at address 63 and count<br>down<br>group erase write entire chip<br>read entire chip | 1-3, 1-5,<br>1-6, 1-8 | 1-3, 1-13         |
| 6-6         | GROUP OPERATION TEST<br>1000 $\mu$ sec erase, 200 $\mu$ sec write<br>checkerboard pattern<br>begin at address 0 and count up<br>group erase write entire chip<br>read entire chip                     | 1-3, 1-5,<br>1-6, 1-8 | 1-3, 1-13         |
| 6-7         | READ DISTURB TEST<br>use data written during test 6-6<br>read data to latch 1000 times<br>read entire chip  | 1-3, 1-5,<br>1-6      | 1-3, 1-14         |

78-0286-TA-16-1



TABLE 1-12  
ERASE RECOVERY TEST LOGICAL FLOW SEQUENCE

| Step | Logical Operation  |
|------|--|
| 1    | Setup CL and $\overline{CS}$ per Fig. 5a                             |
| 2    | J = 1  |
| 3    | Block Erase per Fig. 5b  |
| 4    | Address = 0  |
| 5    | Setup Address Lines per Fig. 5c                                      |
| 6    | Data = (per Note at Bottom of Page)                                  |
| 7    | Load Shift Register per Fig. 5d                                      |
| 8    | Write Data per Fig. 5e   |
| 9    | Address = Address + 1  |
| 10   | If (Address < 64) then 5   |
| 11   | J = J + 1  |
| 12   | If (J < 101) then 3  |
| 13   | Block Erase per Fig. 5b  |
| 14   | Address = 0  |
| 15   | Setup Address Lines per Fig. 5c                                      |
| 16   | Data = (Complement of Data used in Step 6)                           |
| 17   | Load Shift Register per Fig. 5d                                      |
| 18   | Write Data per Fig. 5e   |
| 19   | Address = Address + 1  |
| 20   | If (Address < 64) then 15  |
| 21   | Address = 0  |
| 22   | Setup Address Lines per Fig. 5c                                      |
| 23   | Read Data to Latch per Fig. 5f                                       |
| 24   | Empty Shift Register per Fig. 5g                                     |
| 25   | If (Data $\neq$ (Complement of Data used in Step 6)) then BIN and 29 |
| 26   | Address = Address + 1  |
| 27   | If (Address < 64) then 22  |
| 28   | Reset $\overline{CS}$ and CL per Fig. 5h                             |
| 29   | End Routine  |

Note:

| Test Number | Data Pattern to be Used in Step 6                       |
|-------------|---|
| 6-1         | All Zero  |
| 6-2         | All One   |
| 6-3         | Checkerboard (Defined in Table 1-6 for Test Number 2-5) |
| 6-4         | Complement Checkerboard                                 |

78-0286-TA-17-1

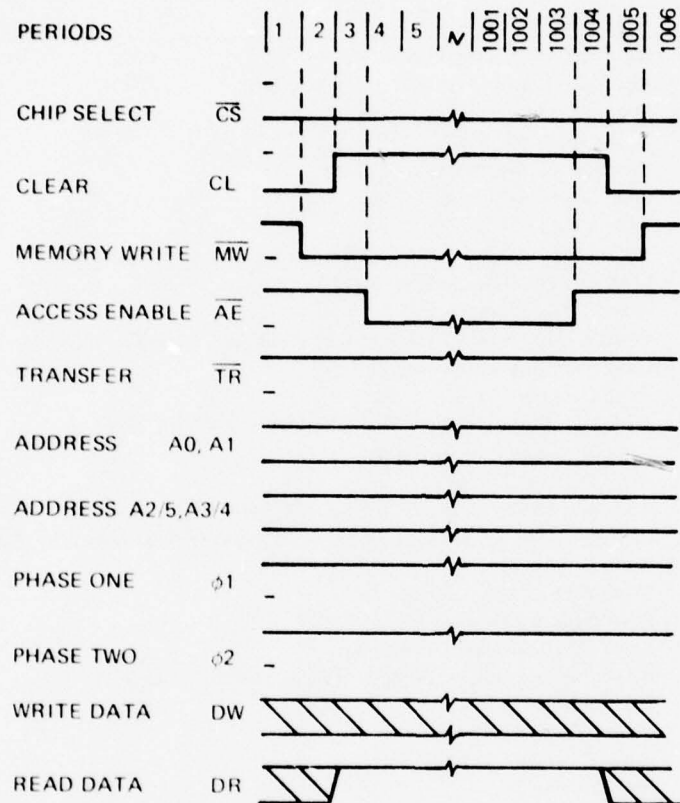
TABLE 1-13  
GROUP OPERATION'S TEST LOGICAL FLOW SEQUENCE


| Step | Logical Operation   |
|------|---|
| 1    | Setup CL and $\overline{CS}$ per Fig. 5a  |
| 2    | Address = (63 for Test 6-5) (0 for Test 6-6)  |
| 3    | Setup Address Lines per Fig. 5c   |
| 4    | Group Erase per Fig. 8  |
| 5    | Data (per Note at Bottom of Page)   |
| 6    | Load Shift Register per Fig. 5d   |
| 7    | Write Data per Fig. 5e  |
| 8    | Address = (Address - 1 for Test 6-5) (Address + 1 for Test 6-6)                       |
| 9    | Load Shift Register per Fig. 5d   |
| 10   | Write Data per Fig. 5e  |
| 11   | Address = (Address - 1 for Test 6-5) (Address + 1 for Test 6-6)                       |
| 12   | Load Shift Register per Fig. 5d   |
| 13   | Write Data per Fig. 5e  |
| 14   | Address = (Address - 1 for Test 6-5) (Address + 1 for Test 6-6)                       |
| 15   | Load Shift Register per Fig. 5d   |
| 16   | Write Data per Fig. 5e  |
| 17   | Address = (Address - 1 for Test 6-5) (Address + 1 for Test 6-6)                       |
| 18   | (If Address $\neq$ -1 then 3 for Test 6-5) (If Address $\neq$ 64 then 3 for Test 6-6) |
| 19   | Address = 0   |
| 20   | Setup Address Lines per Fig. 5c   |
| 21   | Read Data to Latch per Fig. 5f  |
| 22   | Empty Shift Register per Fig. 5g  |
| 23   | If Data $\neq$ (per Note at Bottom of Page) then BIN and 26                           |
| 24   | Address = Address + 1   |
| 25   | If Address $\neq$ 64 then 20  |
| 26   | Reset $\overline{CS}$ and CL per Fig. 5h  |
| 27   | End Routine   |

Note

| Test Number | Data Pattern  |
|-------------|---|
| 6-5         | Complement Checkerboard                                 |
| 6-6         | Checkerboard (Defined in Table 1-6 for Test Number 2-5) |

78-0286-TA-18-1



- NOTES:
- 1 A period is 1 microsecond.
  - 2 No transitions occur within a period.
  - 3 Rise and fall times (10% to 90%)  $\leq 50\text{ns}$
  - 4  don't care condition.

78-0286 VA-19

Figure 1-8. Operating Waveform Sequence for Group Erase

checkerboard bar patterns.

The use of address unique data verified that every cell could be accessed. The use of the additional data patterns eliminated the possibility of hard cell (stuck at one or stuck at zero) failures.

This straightforward test sequence provides a first order verification of device operation. The use of a limited number of data patterns is believed to be adequate for MNOS type devices because the classical problem of pattern sensitivity does not exist.

Volatile semiconductor memories have in some cases been found to operate improperly as a function of particular data patterns. In dynamic RAM's for example, data stored as charge on capacitive nodes can be disturbed by the transient conditions surrounding a given cell. Transients can also act to disturb the proper operation of other parts of the memory circuit.

Complex three dimensional distributed capacitive networks exist within these chips, and it is difficult to predict all possible modes of charge

TABLE 1-14  
READ DISTURB TEST LOGICAL FLOW SEQUENCE

| Step | Logical Operation                             |
|------|---|
| 1    | Setup CL and $\overline{CS}$ per Fig. 5a      |
| 2    | $J = 1$                                       |
| 3    | Address = 0                                   |
| 4    | Setup Address Lines per Fig. 5c               |
| 5    | Read Data to Latch per Fig. 5f                |
| 6    | Address = Address + 1                         |
| 7    | If (Address $\leq 64$ ) then 4                |
| 8    | $J = J + 1$                                   |
| 9    | If ( $J \leq 1001$ ) then 3                   |
| 10   | Address = 0                                   |
| 11   | Setup Address Lines per Fig. 5c               |
| 12   | Read Data to Latch per Fig. 5f                |
| 13   | Empty Shift Register per Fig. 5g              |
| 14   | If (Data $\neq$ Checkerboard) then BIN and 18 |
| 15   | Address = Address + 1                         |
| 16   | If (Address $\leq 64$ ) then 11               |
| 17   | Reset $\overline{CS}$ and CL per Fig. 5h      |
| 18   | End Routine                                   |

Note

Checkerboard Pattern Defined in Table 1-6 for Test Number 2-5

78 0286 TA 20 1



transfer. From a test standpoint attempts are made to cause changes in cell data in the presence of all possible adjacent cell conditions. Many subtle situations can exist within an array, and exhaustive testing is not economically feasible.

MNOS memory devices store information as charge trapped within the memory transistor gate insulator. This charge is very difficult to disturb as a function of normal circuit operating transients. The storage cell is in effect immune from the classical pattern sensitivity mechanism associated with charge storage on capacitive nodes.

Freedom from pattern sensitivity effects has been examined by exploratory tests with a wide variety of data patterns conducted at the Naval Air Test Center. Devices in a BORAM advanced development unit were exercised under computer control with no observed pattern related failures.

#### 1.2.2 Retention Screen

The nonvolatile nature of MNOS memory poses a special test problem. Examination of memory transistor threshold decay characteristics, and experience with BORAM devices, leads to the expectation of several years of unpowered data retention. Since the beginning of BORAM development efforts the retention goal has been 4,000 hours. The testing problem boils down to finding some meaningful measurement performed in milliseconds on automatic equipment which can predict performance over a 4,000-hour period.

Researchers at Westinghouse and elsewhere have examined this problem and have proposed different approaches which have merit. The utility of specific techniques must be judged in the context of the device involved. Economic objectives, packaging and part circuit design must be considered.

The approach used for the BORAM 6002 is to screen for homogeneous memory cell characteristics. The implicit assumption is that defect free devices are capable of meeting retention goals. If a given device differs significantly from the parent population, it is viewed as a potential retention failure.

To communicate clearly the test rational it is first necessary to outline the operation of a memory cell. The BORAM 6002 employs two MNOS memory transistors to store one bit of information. The detection of stored data involves a differential comparison of the threshold voltage states of the two transistors. Storage of a ONE is defined when one transistor is in a high conduction (VHC) state and the other is in a low conduction (VLC) state. Storage of a ZERO is defined when the two transistors are in states opposite that for a stored ONE.

In a defect free device the threshold difference between the two transistors is quite large immediately after data storage. As time goes by, both transistor thresholds decay slowly in such a manner that the difference decreases. The end of retention occurs when the difference becomes so small it can not be reliably detected by the sense amplifier. The retention period for a device depends on the size of the initial difference (window) and the rate of decay of the difference.

The process of storing information involves two steps. The initial operation is called "clear" or "erase". Both transistors in the cell are subjected to a 1 millisecond +25 volt gate to substrate pulse. Both transistors are shifted to the high conduction (VHC) threshold state. In this case the cell does not contain any meaningful data... i. e. when both transistors are in the high conduction state the cell content is logically indeterminate.

The second operation called "writing" acts to shift one of the transistors in the cell to the low conduction state as a function of the data input signal. The transistor to be written is subjected to a -25 volt 200 microsecond gate to source pulse. After this operation the cell is in a logically determinate state. One transistor remains in the cleared condition, and the other transistor has been written.

The threshold voltage window between the two transistors in a cell depends on the amplitude and duration of the pulses used for erase and write. Small windows which simulate end-of-retention conditions can be achieved by using

smaller amplitudes and/or shorter pulsewidths.

In a BORAM 6002 device, the option of using narrow erase or write pulsewidths is not practical. The memory transistor will respond to microsecond pulses. This time is so short that the propagation delays in the peripheral on-chip circuitry would dominate circuit performance.

The choice of end-of-retention simulation by reduced pulse amplitudes is easily accomplished, and can be performed in such a manner as to avoid confusing cell operation and peripheral circuit operation.

Experiments with individual memory transistors illustrate the concepts involved. Figure 1-9 shows how the decay characteristic curves for a BORAM transistor change as the amplitudes of the erase and write voltages are changed. At reduced voltages the window closes up in a predictable manner. At  $\pm 25$  volts the projected window closure point was off scale. At  $\pm 23$  volts closure occurs at about 10,000 hours. For  $\pm 21$  volts the window closes in less than 1 hour. This of course is no surprise. The threshold voltage shift achieved at any given erase and write pulsewidth is directly proportional to the erase and write amplitude.

Figure 1-10 illustrates how a reduced threshold window established by a  $\pm 21$  volt pulse could be used to screen product. In this experiment five devices were observed at the  $\pm 21$  volt condition. Four of the devices were known to have characteristics typical of the parent device population. The fifth device was known to exhibit nontypical pulse response characteristics. If a test were performed using a 30 second read delay time, the maveric sample could be distinguished from the typical population.

This then is the general concept for a screen to detect memory cells with potential retention (and/or endurance) problems. One further refinement was introduced to make the screen more relevant to actual device operating conditions. The erase voltage was held at nominal amplitude. Only the write voltage was reduced.

The normal condition for writing is for the memory transistor to be initially

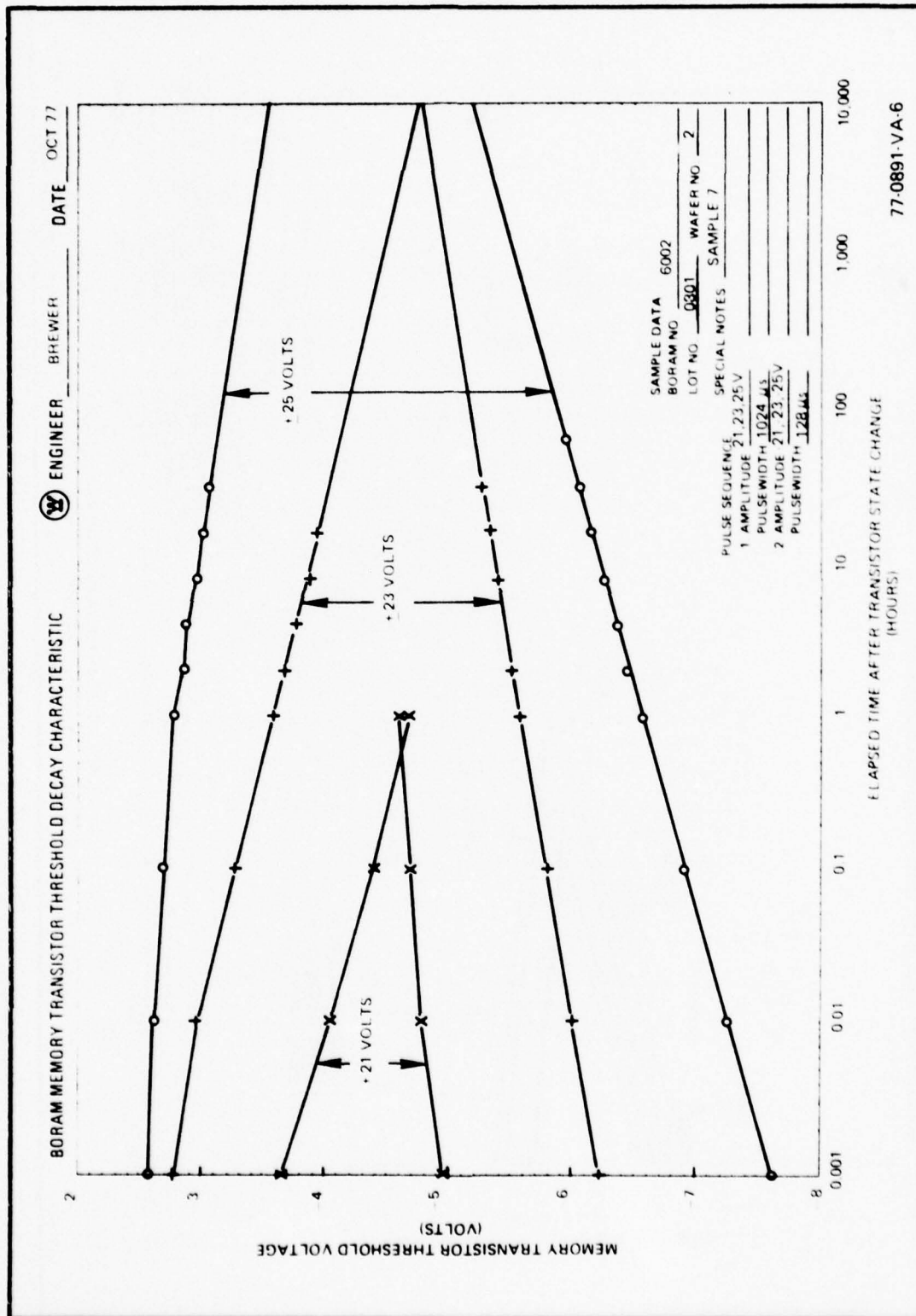
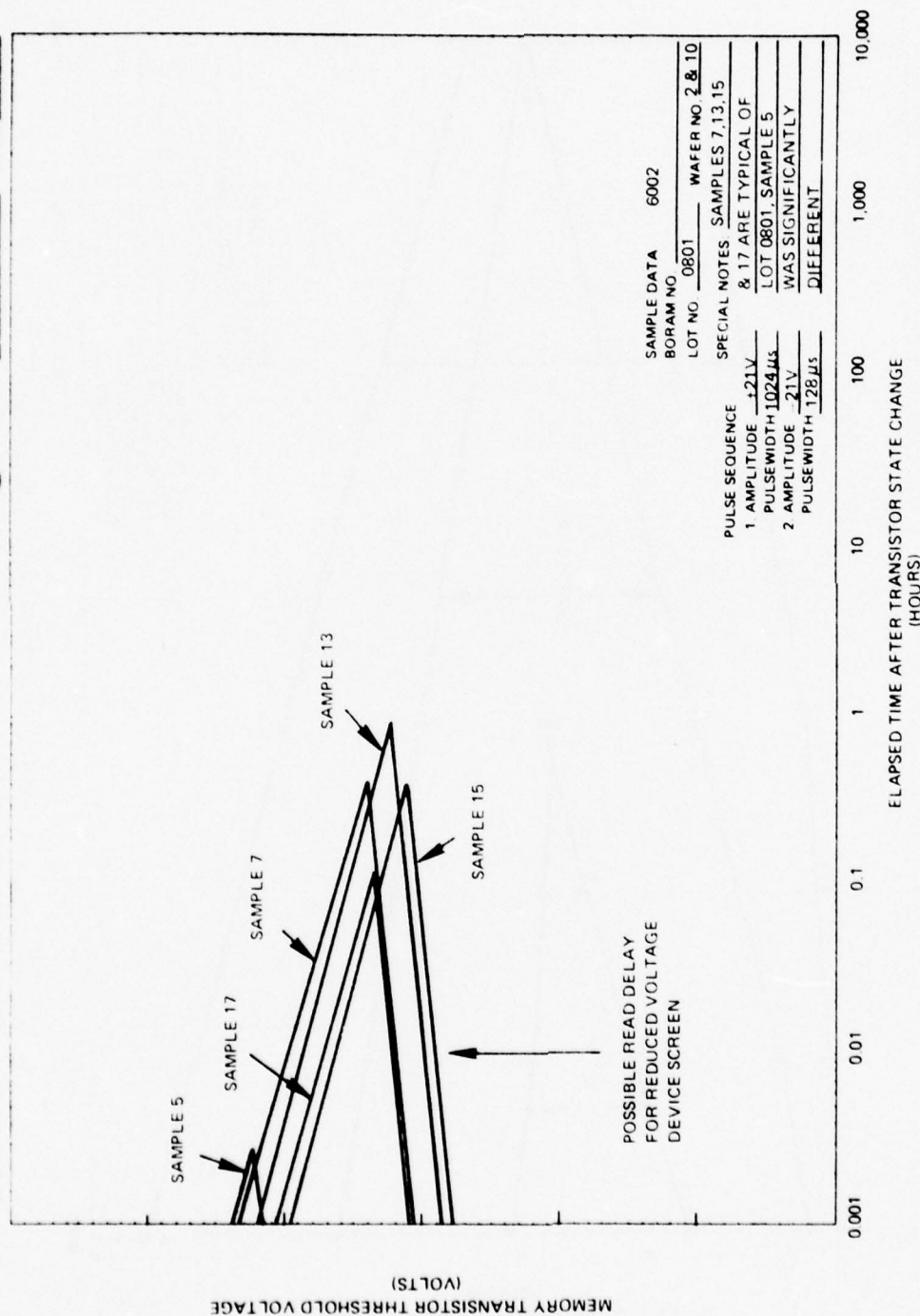


Figure 1-9. Threshold Voltage Window for Three Write/Erase Voltage Amplitudes





77-0891-VA-5

Figure 1-10. Threshold Voltage Windows for Reduced Voltage Screen

in a saturated high conduction state. If the erase voltage amplitude were reduced this initial condition would be changed. The write pulse response would in effect be tested in the non-saturated mode - a condition which should never exist.

Paragraph 1.1.2.4 presented a description of exactly how the retention screen was mechanized for the characterization project. Erase and read operations were performed at nominal supply voltages. The VGG supply voltage was progressively reduced in 0.5 volt decrements for writing until a data read out failure occurred.

Table 1-15 shows the results obtained from the characterization test on BORAM 6002 devices. Figure 1-11, 1-12 and 1-13 show the distributions of pass voltages at each temperature. Apparently the circuit enjoys the greatest operating margin at high temperature. In practice this screening technique would be used only at room temperature.

On the basis of this limited amount of distribution data a retention screen

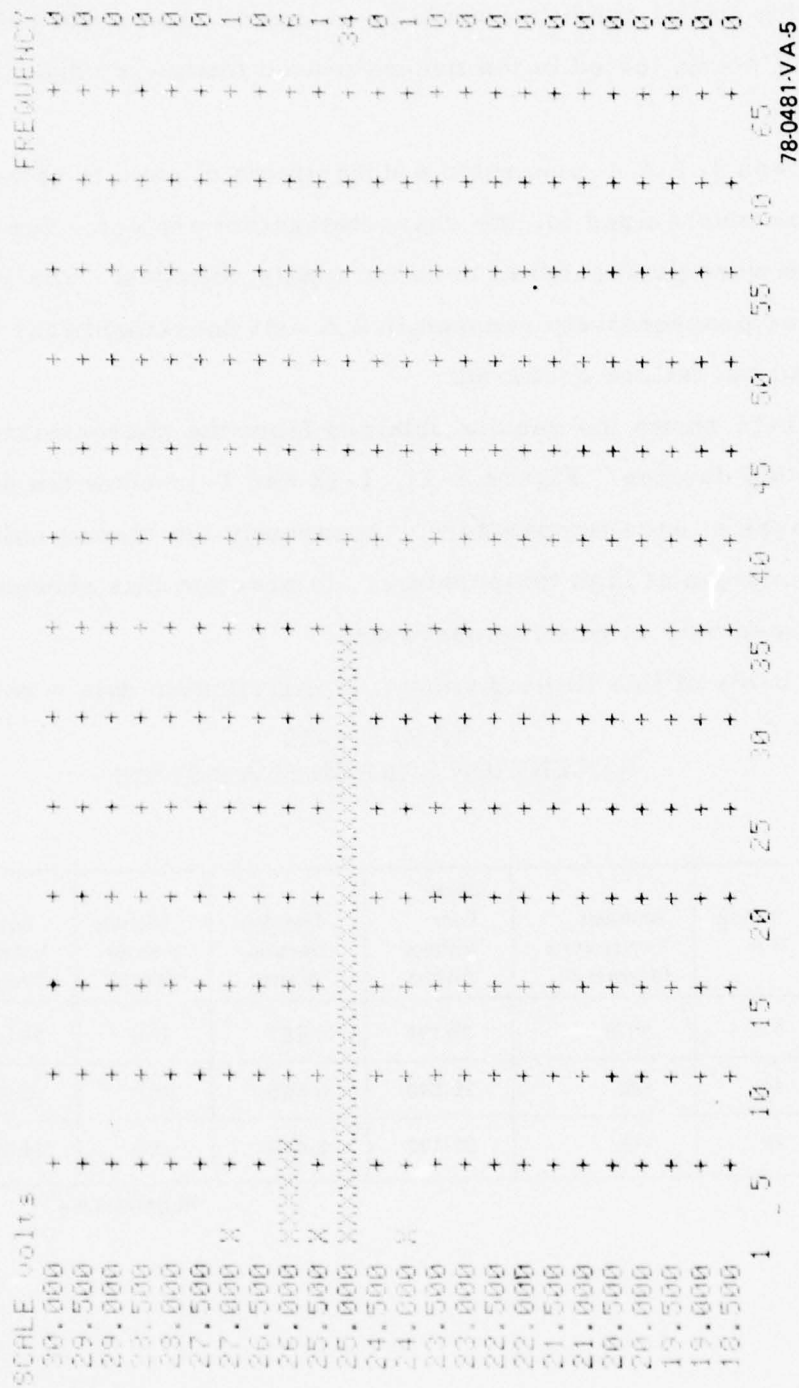
TABLE 1-15  
RETENTION SCREEN STATISTICS

| Sample Size | Ambient Temperature (degrees C) | Mean Pass Voltage (Volts) | Standard Deviation (Volts) | Highest Voltage (Volts) | Lowest Voltage (Volts) |
|-------------|---------------------------------|---------------------------|----------------------------|-------------------------|------------------------|
| 43          | +125                            | 25.174                    | 0.487                      | 27.0                    | 24.00                  |
| 44          | +25                             | 25.648                    | 0.695                      | 28.0                    | 25.00                  |
| 29          | -55                             | 26.172                    | 0.879                      | 28.0                    | 24.00                  |

78-0481-TA-4

BOEAM 6002 TEST SUMMARY  
 TEST 4-01 RETENTION TEST  
 VCG Terminal under test

29 APR 78 43 Samples  
 Test temperature +125 degrees C



78-0481-VA-5

Figure 1-11. Retention Test 125°C Histogram

BORAM 600C TEST SUMMARY  
 TEST 4-01 RETENTION TEST  
 VCG Terminal under test

20 APR 78

44 Samples  
 Test temperature +025 degrees C

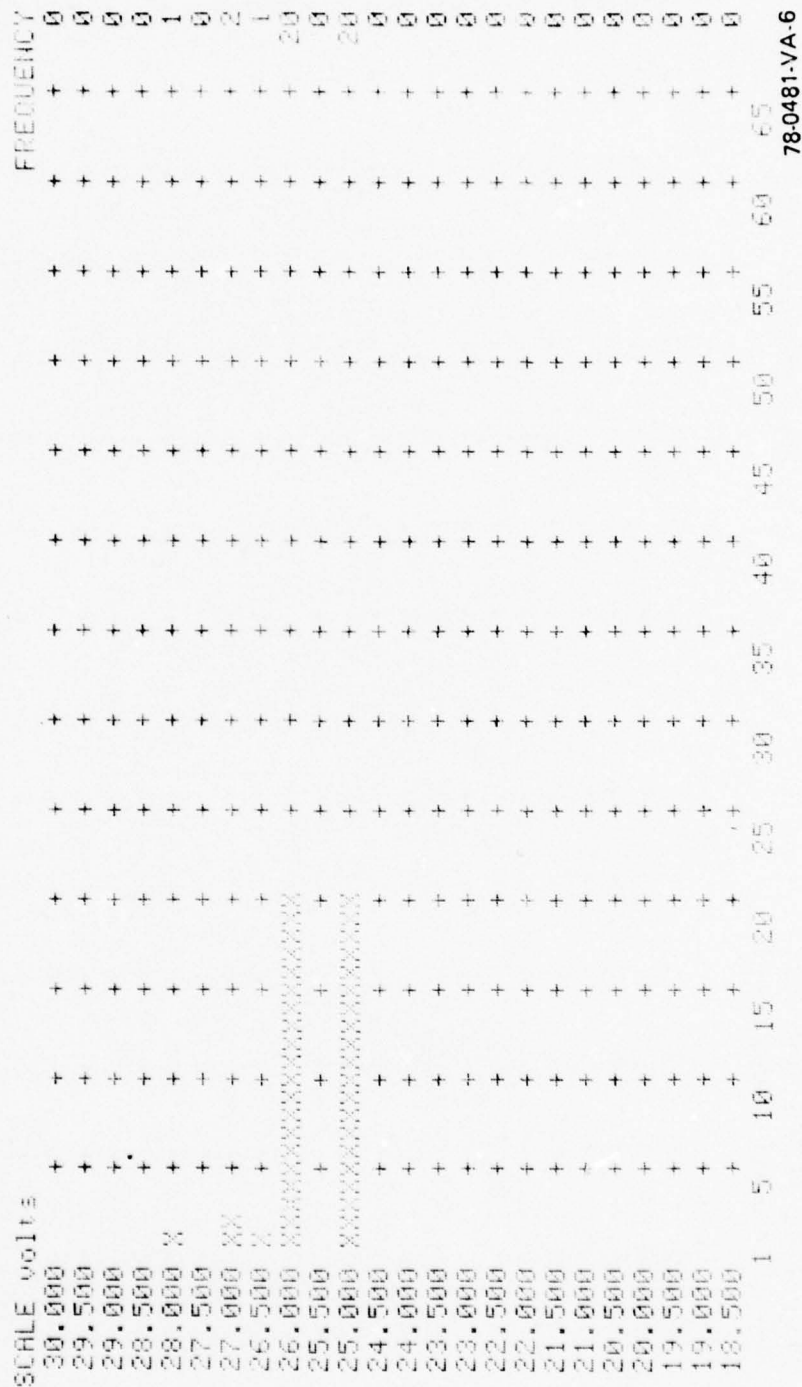


Figure 1-12. Retention Test 25°C Histogram



BURAM 6002 TEST SUMMARY  
 TEST 4-01 RETENTION TEST  
 VCG Terminal under test

20 APR 78 29 Samples  
 Test temperature -55 degrees C

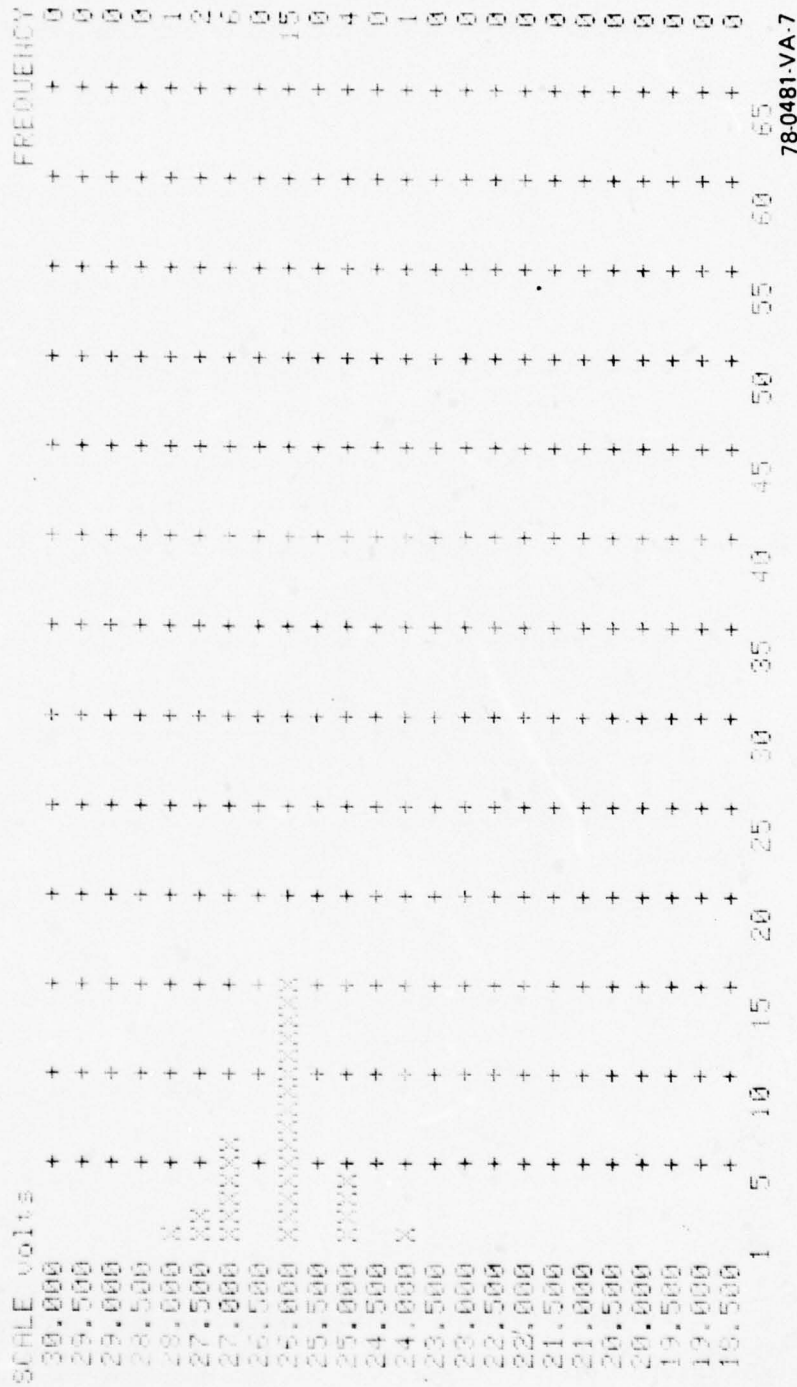


Figure 1-13. Retention Test -55°C Histogram

test limit of 27 volts has been established for wafer probe test. In this case the parts will be required to pass a zero pattern and a one pattern written with VGG at -27 volts.

As a follow up action it is planned to identify a number of die which fail this criteria. These parts will be packaged, tested using the characterization program, and observed for retention properties.

### 1.2.3 Erase Recovery Tests

The purpose of "Erase Recovery" tests is to examine each cell for adequate pulse response. The operation of an MNOS BORAM memory cell is dependent on the past history of data storage. As documented in paragraph 1.1.2.6 four tests are performed which store the complement of a particular data pattern 100 times, then store the data pattern one time. The last data pattern is read back to verify chip operation.

This constitutes a worst case situation for normal device operation. One transistor in the cell is erased 101 times, and then is written. The "erase recovery" name describes this case. The other transistor is erased and written alternately 100 times, and then is erased once.

The transistor which was erased 101 times can be expected to be in hard saturation. After writing this device with a single pulse the least negative threshold voltage level associated with normal cell operation can be expected. The second transistor is pulsed from the written state to the cleared state. This is also the most marginal erase condition.

Empirical results tend to support the need for an erase recovery test. Devices with marginal pulse response are detected. These same devices can pass a simple erase write of several patterns. Use of single erase write tests with marginal pulse response devices shows nonrepeatable results.

In planning the erase recovery test sequence the question of assuring margins had to be considered. One aspect of this matter is the choice of the number of times the pattern should be stored before reversal. On small samples of parts no difference was noted between 100 and 10 repetitions.

The smaller number was finally selected to save test time at wafer test.

Other alternatives for insuring operating margins will be explored in the future. For example, it may be desirable to use a reduced VGG voltage or narrow pulse widths when the last data pattern is written.

#### 1.2.4 Group Operations Test

The BORAM 6002 device may be erased in the chip mode or the group mode. A chip erase affects all 2048 cells in the device. A group erase operates only on 128 bits associated with four rows in the RAM.

The term "group" was derived from nomenclature used to describe the data organization within BORAM storage systems. The choice of a 128 bit clear was made after a study of the data block sizes required by different users.

A point of concern with group mode operation was to be sure that clearing one group did not disturb the contents of unaddressed groups. The group operations test was designed to efficiently verify the absence of gross disturb effects while confirming proper memory operation.

The scheme employed was to begin at the high order address and go through the entire chip erasing and writing groups. Then the entire chip is read. The procedure is then repeated with the complementary data pattern beginning at the low order address. In this manner each is exposed to whatever transients are associated with adjacent group erase.

#### 1.2.5 Read Disturb Tests

To read the contents of a storage cells it is necessary to operate the two transistors in some manner that will compare the threshold voltages and yield a logical one or zero output. If the reading process causes a threshold shift, a disturb effect is said to exist. The magnitude and nature of disturb effects are a function of the design of the read circuitry.

In the BORAM 6002 chip the memory transistors are operated as source followers for reading. Disturb effects are believed to be minimal. By design, any disturb action should enhance the written state. If a device is read

continuously the net disturb action should increase the threshold voltage window, and should extend the nonvolatile data retention time.

A read disturb test was included in the characterization program with some mixed feelings about its utility. Army specification SCS503 requires that each chip be demonstrated as being capable of 10 reads without loss of data. The characterization program performs 1000 read operations. In samples tested to date, no part which has passed the functional test requirements has failed the read disturb test.

It appears that a more meaningful investigation of possible read disturb action should cycle parts out to  $10^{11}$  or  $10^{12}$  reads. The relationship between retention and reading should be treated, and possible changes in characteristics with endurance cycling should be examined. These experiments were beyond the scope of the present study.

### 1.3 STATIC PARAMETER TESTS AND RESULTS

Table 1-7 in text above listed 20 static parameter tests which were included in the characterization program. This discussion will review the rationale for each group of tests, and will present test results.

#### 1.3.1 Data Summary

Tables 1-16, 1-17 and 1-18 provide a statistical summary of test results obtained from the characterization program at 125°C, 25°C and -55°C. The data is identified by test number. The static parameter tests are numbered 3-01 to 3-20. These tables were prepared by the data reduction program discussed in paragraph 1.1.3.

#### 1.3.2 Leakage Current Observations

The conceptually simple measurement of leakage current involves some problems which require practical compromises. These measurements are performed to detect gross insulator or reverse biased junction defects. A voltage difference between the terminal under test and all other device terminals is forced, and the resulting current flow is measured.

A typical input node may exhibit a few picoamperes of current. A few



TABLE 1-16  
STATIC PARAMETER 125°C TEST RESULTS

| SOPAM 2002 TEST SUMMARY         |           | 20 APR 78 |                  | 43 Samples           |                      |        |        |
|---------------------------------|-----------|-----------|------------------|----------------------|----------------------|--------|--------|
| Test temperature +125 degrees C |           |           |                  |                      |                      |        |        |
| TEST NUMBER                     | UNITS     | MEAN      | STD DEV<br>signd | HI LIMIT<br>+3 signd | LO LIMIT<br>-3 signd | HIGH   | LOW    |
| 3-01                            | microamps | 0.969     | 2.469            | 8.375                | 0.000                | 10.240 | 0.005  |
| 3-02                            | microamps | 0.044     | 0.024            | 0.116                | 0.000                | 0.105  | 0.005  |
| 3-03                            | microamps | 0.044     | 0.027            | 0.124                | 0.000                | 0.125  | 0.005  |
| 3-04                            | microamps | 0.047     | 0.028            | 0.133                | 0.000                | 0.125  | 0.005  |
| 3-05                            | microamps | 0.050     | 0.031            | 0.153                | 0.000                | 0.140  | 0.010  |
| 3-06                            | microamps | 0.204     | 1.554            | 4.946                | 0.000                | 10.235 | 0.005  |
| 3-07                            | microamps | 0.313     | 1.554            | 4.975                | 0.000                | 10.235 | 0.005  |
| 3-08                            | microamps | 0.046     | 0.025            | 0.121                | 0.000                | 0.115  | 0.005  |
| 3-09                            | microamps | 0.039     | 0.023            | 0.107                | 0.000                | 0.095  | 0.005  |
| 3-10                            | microamps | 0.040     | 0.026            | 0.117                | 0.000                | 0.105  | 0.005  |
| 3-11                            | microamps | 0.050     | 0.036            | 0.120                | 0.000                | 0.150  | 0.005  |
| 3-12                            | microamps | 0.030     | 0.022            | 0.104                | 0.000                | 0.110  | 0.005  |
| 3-13                            | volts     | 12.652    | 0.230            | 13.493               | 11.812               | 13.250 | 12.100 |
| 3-14                            | volts     | 1.613     | 0.158            | 2.087                | 1.138                | 1.950  | 1.000  |
| 3-15                            | microamps | 1.237     | 7.232            | 22.934               | 0.000                | 47.550 | 0.050  |
| 3-16                            | milliamps | 9.120     | 0.054            | 11.633               | 6.557                | 11.150 | 7.800  |
| 3-17                            | milliamps | 19.864    | 2.509            | 27.491               | 12.437               | 24.800 | 15.900 |
| 3-18                            | milliamps | 16.414    | 1.602            | 23.461               | 13.367               | 22.450 | 15.750 |
| 3-19                            | milliamps | 9.041     | 0.834            | 11.542               | 6.539                | 11.050 | 7.750  |
| 3-20                            | milliamps | 11.053    | 1.073            | 14.274               | 7.833                | 13.700 | 9.400  |
| 3-01                            | volts     | 25.174    | 0.487            | 26.634               | 23.715               | 27.000 | 24.000 |
| 3-01                            | volts     | 2.330     | 0.054            | 2.522                | 2.135                | 2.515  | 2.005  |
| 3-02                            | volts     | 2.969     | 1.893            | 8.538                | 0.000                | 11.050 | 2.000  |
| 3-03                            | volts     | 12.109    | 2.135            | 18.519               | 5.736                | 19.350 | 2.000  |
| 3-04                            | volts     | 2.174     | 0.114            | 2.515                | 1.034                | 2.550  | 1.900  |
| 3-05                            | volts     | 26.020    | 0.175            | 26.557               | 25.499               | 26.400 | 25.550 |

78-0481-VA-8

78-0481-VA-8

TABLE 1-17  
STATIC PARAMETER 25°C TEST RESULTS

| FORAN 2002 TEST SUMMARY         |           |        |         | 20 APR 70            |                      | 44 Samples |        |
|---------------------------------|-----------|--------|---------|----------------------|----------------------|------------|--------|
| Test Temperature +025 degrees C |           |        |         |                      |                      |            |        |
| TEST NUMBER                     | UNITS     | MEAN   | STD DEV | HI LIMIT<br>+3 s1900 | LO LIMIT<br>-3 s1900 | HIGH       | LOW    |
| 3-01                            | microamps | 0.809  | 2.459   | 8.188                | 0.000                | 10.240     | 0.010  |
| 3-02                            | microamps | 0.041  | 0.013   | 0.081                | 0.001                | 0.085      | 0.020  |
| 3-03                            | microamps | 0.022  | 0.009   | 0.047                | 0.000                | 0.045      | 0.005  |
| 3-04                            | microamps | 0.028  | 0.008   | 0.052                | 0.004                | 0.045      | 0.005  |
| 3-05                            | microamps | 0.028  | 0.012   | 0.064                | 0.000                | 0.085      | 0.015  |
| 3-06                            | microamps | 0.255  | 1.540   | 4.874                | 0.000                | 10.235     | 0.010  |
| 3-07                            | microamps | 0.207  | 1.539   | 4.884                | 0.000                | 10.236     | 0.010  |
| 3-08                            | microamps | 0.029  | 0.009   | 0.057                | 0.001                | 0.045      | 0.015  |
| 3-09                            | microamps | 0.026  | 0.007   | 0.048                | 0.005                | 0.040      | 0.010  |
| 3-10                            | microamps | 0.036  | 0.049   | 0.184                | 0.000                | 0.350      | 0.015  |
| 3-11                            | microamps | 0.025  | 0.006   | 0.043                | 0.007                | 0.040      | 0.015  |
| 3-12                            | microamps | 0.011  | 0.004   | 0.023                | 0.000                | 0.020      | 0.005  |
| 3-13                            | volts     | 12.989 | 0.238   | 13.702               | 12.275               | 13.500     | 12.550 |
| 3-14                            | volts     | 1.384  | 0.131   | 1.777                | 0.991                | 1.650      | 1.150  |
| 3-15                            | microamps | 1.522  | 9.623   | 30.991               | 0.000                | 63.900     | 0.050  |
| 3-16                            | milliamps | 11.025 | 0.952   | 13.882               | 8.168                | 13.150     | 9.350  |
| 3-17                            | milliamps | 24.050 | 3.274   | 30.886               | 14.239               | 29.300     | 18.800 |
| 3-18                            | milliamps | 21.989 | 2.512   | 29.526               | 14.451               | 26.100     | 16.850 |
| 3-19                            | milliamps | 10.902 | 0.941   | 13.724               | 8.080                | 13.000     | 9.250  |
| 3-20                            | milliamps | 13.234 | 1.202   | 15.841               | 9.627                | 15.800     | 11.200 |
| 4-01                            | volts     | 25.640 | 0.695   | 27.734               | 23.562               | 28.000     | 25.000 |
| 5-01                            | volts     | 2.394  | 0.053   | 2.582                | 2.206                | 2.580      | 2.285  |
| 5-02                            | volts     | 2.932  | 1.523   | 7.802                | 0.000                | 9.800      | 2.350  |
| 5-03                            | volts     | 12.394 | 2.173   | 18.913               | 5.876                | 13.500     | 2.350  |
| 5-04                            | volts     | 3.459  | 0.453   | 4.819                | 2.099                | 4.100      | 2.350  |
| 5-05                            | volts     | 26.059 | 0.252   | 26.814               | 25.304               | 27.000     | 25.600 |

78-0481-VA-9

78-0481-VA-9

TABLE 1-18  
STATIC PARAMETER -55°C TEST RESULTS

| SOPAN 6602 TEST SUMMARY        |           |        |               | 20 APR 78         |                   | 24 Samples |        |
|--------------------------------|-----------|--------|---------------|-------------------|-------------------|------------|--------|
| Test temperature -55 degrees C |           |        |               |                   |                   |            |        |
| TEST NUMBER                    | UNITS     | MEAN   | STD DEV sigma | HI LIMIT +3 sigma | LO LIMIT -3 sigma | HIGH       | LOW    |
| 3-01                           | microamps | 7.213  | 3.057         | 16.384            | 0.000             | 10.240     | 0.100  |
| 3-02                           | microamps | 6.171  | 3.397         | 16.353            | 0.000             | 10.235     | 0.130  |
| 3-03                           | microamps | 6.937  | 3.650         | 17.886            | 0.000             | 10.235     | 0.060  |
| 3-04                           | microamps | 3.977  | 3.885         | 14.131            | 0.000             | 10.235     | 0.045  |
| 3-05                           | microamps | 5.968  | 3.525         | 16.482            | 0.000             | 10.235     | 0.030  |
| 3-06                           | microamps | 8.227  | 3.313         | 18.167            | 0.000             | 10.235     | 0.325  |
| 3-07                           | microamps | 8.646  | 3.115         | 16.491            | 0.801             | 10.235     | 1.975  |
| 3-08                           | microamps | 7.472  | 3.574         | 19.193            | 0.000             | 10.235     | 0.120  |
| 3-09                           | microamps | 7.385  | 3.324         | 17.359            | 0.000             | 10.235     | 1.510  |
| 3-10                           | microamps | 4.556  | 3.543         | 15.185            | 0.000             | 10.235     | 0.055  |
| 3-11                           | microamps | 8.007  | 3.378         | 18.142            | 0.000             | 10.235     | 0.355  |
| 3-12                           | microamps | 5.398  | 3.182         | 14.944            | 0.000             | 10.235     | 0.055  |
| 3-13                           | volts     | 13.443 | 0.202         | 14.048            | 12.838            | 13.890     | 12.950 |
| 3-14                           | volts     | 1.684  | 0.124         | 1.456             | 0.712             | 1.450      | 0.900  |
| 3-15                           | microamps | 17.030 | 31.639        | 110.153           | 0.000             | 102.440    | 0.300  |
| 3-16                           | milliamps | 14.522 | 0.892         | 17.197            | 11.848            | 17.250     | 12.450 |
| 3-17                           | milliamps | 31.884 | 4.703         | 45.895            | 17.774            | 39.700     | 23.550 |
| 3-18                           | milliamps | 29.053 | 1.905         | 34.767            | 23.340            | 34.050     | 24.750 |
| 3-19                           | milliamps | 14.176 | 0.865         | 16.722            | 11.580            | 17.100     | 12.350 |
| 3-20                           | milliamps | 16.910 | 1.065         | 20.104            | 13.717            | 20.550     | 14.700 |
| 4-01                           | volts     | 26.172 | 0.679         | 28.810            | 23.535            | 28.000     | 24.000 |
| 5-01                           | volts     | 2.307  | 0.472         | 3.724             | 0.889             | 2.535      | 0.800  |
| 5-02                           | volts     | 2.669  | 1.959         | 8.747             | 0.000             | 9.750      | 0.600  |
| 5-03                           | volts     | 11.433 | 3.922         | 23.193            | 0.000             | 13.300     | 0.050  |
| 5-04                           | volts     | 4.014  | 0.442         | 5.333             | 3.589             | 4.450      | 3.500  |
| 5-05                           | volts     | 25.271 | 0.970         | 28.181            | 22.351            | 25.900     | 21.350 |

78-0481-VA-10

78-0481-VA-10

nodes may have microampere level currents. The wide variation of current values and the need to set a measurement scale for automatic test equipment is in conflict. For the characterization program, measurements were performed using a 10 microampere full scale setting. For this condition the equipment accuracy is  $\pm 0.05$  microamperes.

This choice of scales allows visibility of only the few current values in the microampere range. All low current readings simply result in random indications on the order of 0.05 microamperes.

During the characterization project measurements were attempted at  $-55^{\circ}\text{C}$ ,  $25^{\circ}\text{C}$  and  $125^{\circ}\text{C}$ . The leakage currents observed at  $-55^{\circ}\text{C}$  were inaccurate because of surface leakage on the test fixtures. A considerable amount of frosting was present during the experiment. Since other data taken at that temperature was valid, and leakage currents are normally well behaved at low temperature, the test was not repeated.

#### 1.3.2.1 Chip Select Leakage

Figures 1-14 and 1-15 show the chip leakage distributions at  $125^{\circ}\text{C}$  and  $25^{\circ}\text{C}$ . At room temperature six parts were observed to have leakage in excess of 0.5 microamperes. Two parts showed full scale readings of 10.240 microamperes.

It appears that the use of 40 volts for this test on the BORAM 6002 is extreme. The tail edge of the normal breakdown characteristic goes below 40 volts. A better choice appears to be 37.5 volts. The high leakage currents observed in the sample were due to junction breakdown, not to defective insulators or junctions. Testing at 37.5 volts allows for more than 5 percent variation in the nominal 35 volt level.

#### 1.3.2.2 CMOS Level Input Leakages

In table 1-3 in the text above it was shown that input signals  $\overline{\text{TR}}$ ,  $\text{A0}$ ,  $\text{A3/4}$ ,  $\text{A1}$ ,  $\text{A2}$ ,  $\phi 2$ ,  $\text{DW}$ ,  $\text{A2/5}$ ,  $\overline{\text{AE}}$ ,  $\overline{\text{MW}}$ , and  $\phi 1$  require signal swings similar to that of CMOS devices operated at 15 volts. Each of these inputs was tested for leakage current at -20 volts. The resulting distributions for all measured inputs combined is presented in figures 1-16 and 1-17.



BURN 0002 TEST SUMMARY  
 TEST 0-01 INPUT LEAKAGE  
 CS Termination under test

20 APR 78

43 Samples  
 Test temperature +125 degrees C

| SCALE MICROAMPS | 1                    | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|----------------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 12.000          | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.500          | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000          | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.500          | XX                   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 10.000          | XX                   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.500           | X                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 8.000           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.000           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000           | X                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 3.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500           | +                    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000           | XX                   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 1.500           | XX                   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000           | XX                   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 0.500           | XXXXXXXXXXXXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 35        |

780481-VA-11

Figure 1-14. Chip Select Leakage Current at 125°C

BURIN 6002 TEST SUMMARY  
 TEST 3-01 INPUT LEAKAGE  
 FS Terminal under test

20 APR 78  
 Test temperature +025 degrees C

44 Samples

| SCALE MICROAMPS                                | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|--|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 12.000   | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.500   | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000   | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.500 XX                                      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 10.000   | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.500  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.500 X  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 8.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.500  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.500  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500 X  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 3.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500 X  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 1.000 X  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 0.500 XX | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 38        |

78-0481-VA-12

Figure 1-15. Chip Select Leakage Current at 25°C

BOFAN 6002 TEST SUMMARY  
 TEST 3-02 to 3-11 LEAKAGES  
 ALL Terminals under test

20 APR 78

430 Samples  
 Test temperature +125 degrees C

| SCALE MICROOHMS | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | F5 | FREQUENCY |
|-----------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 12.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.500          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.500 XX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 10.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 0.500 XX        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 427       |

78-0481-VA-13

Figure 1-16. CMOS Level Input Leakages at 125°C

BORAM 6003 TEST SUMMARY 20 APR 78 440 Samples  
 TEST 3-02 to 3-11 LEAKAGES Test temperature +025 degrees C  
 ALL Terminals under test

| SCALE microamps | 1      | 5      | 10     | 15     | 20     | 25     | 30     | 35     | 40     | 45     | 50     | 55     | 60     | 65     | FREQUENCY |
|-----------------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|-----------|
| 12.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 11.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 11.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 10.500 XX       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 2         |
| 10.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 9.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 9.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 8.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 8.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 7.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 7.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 6.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 6.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 5.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 5.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 4.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 4.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 3.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 3.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 2.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 2.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 1.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 1.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 0.500           | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | 438       |

78-0481-VA-14

Figure 1-17. CMOS Level Input Leakages at 25° C



### 1.3.2.3 Tristate Leakage

The output driver in the BORAM 6002 chip enters a high impedance state when chip select  $\overline{CS}$  is high. This feature allows chips in the BORAM hybrid circuit to be OR tied to a common output bus.

The tristate leakage test stresses the PN junction associated with the output drive DR terminal at 20 volts. Normal usage stress is less than 15 volts. The resulting leakage current distributions are shown in figures 1-18 and 1-19 for 125°C and 25°C.

BORAM 6992 TEST SUMMARY  
 TEST 3-12 TRISTATE LEAKAGE  
 DR Terminal under test

20 APR 78

43 Samples  
 Test temperature +125 degrees C

| SCHLE microamps | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 0.120           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.115           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.110 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.105           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.100           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.095           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.090           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.085 XX        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.080           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.075           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.070           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.065 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.060 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.055 XXXX+     | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.050 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.045 XXXXXXXX  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.040 XXXX+     | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.035 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.030 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.025 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.020 XXXXX     | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.015 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.010 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.005 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1               | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-15

Figure 1-18. Tristate Leakage at 125°C

BORM 6002 TEST SUMMARY  
 TEST 3-12 TRISTATE LEAKAGE  
 DR Terminal under test

20 APR 78 44 Samples  
 Test temperature +025 degrees C

| SCALE microamps | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 0.120           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.115           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.110           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.105           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.100           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.095           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.090           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.085           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.080           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.075           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.070           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.065           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.060           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.055           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.050           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.045           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.040           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.035           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.030           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.025           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.020           | XXX        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 0.015           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 10        |
| 0.010           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 23        |
| 0.005           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 8         |

78-0481-VA-16

Figure 1-19. Tristate Leakage at 25°C

### 1.3.3 I/O Voltage Level Tests

Tests 3-13 and 3-14 of the characterization program were somewhat unusual in that several conventional device parameters are examined simultaneously. The characteristics of the on-chip two phase dynamic shift register are exploited to allow an examination of VIL, VIH, VOL and VOH. When both clock phases  $\phi 1$  and  $\phi 2$  are held low, the signal at the register input DW will ripple through the register and appear at the output DR.

#### 1.3.3.1 Output Low Voltage Observations

To verify VOL (DR) and VIL (DW,  $\phi 1$  and  $\phi 2$ ) the inputs are set at a 0.25 volt guardband inside the levels given in table 1-3. DW is set at -10.25 volts. Both  $\phi 1$  and  $\phi 2$  are set at -14 volts. This combination constitutes the worst set of input levels to maintain the output in a low state. To check VOL the voltage from VCC to DR is measured when 5 milliamperes is forced into DR.

Figures 1-20, 1-21 and 1-22 present the results of this measurement at 125°C, 25°C and -55°C. The standard VOL voltage level for CMOS operated at a VDD of +15 volts is  $(15 \times 0.3) + 4.5$  volts. The equivalent level referred to VCC is -10.5 volts. Note that the samples were able to sink 5 milliamperes over the temperature range and remain well below -10.5 volts.



BOKAM 6082 TEST SUMMARY  
 TEST 3-13 I/O LOW VOLTAGE  
 DR Terminal under test

20 APR 78

43 Samples  
Test temperature +125 degrees C

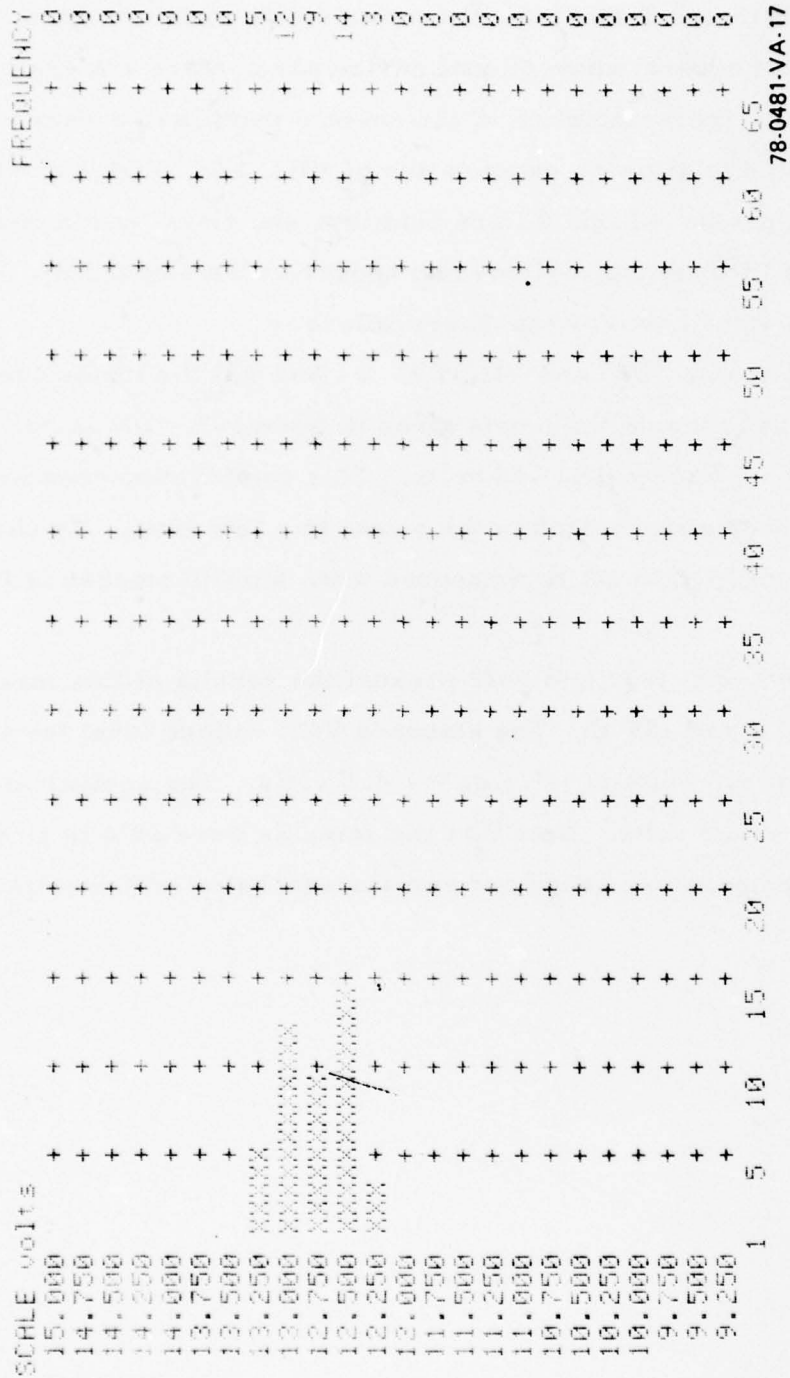


Figure 1-20. I/O Low Voltage Distribution at 125°C

BORM 6002 TEST SUMMARY  
 TEST 3-13 I/O LOW VOLTAGE  
 DR Terminal under test

20 APR 78

44 Samples

Test temperature +025 degrees C

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 15.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.750      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.250      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.750      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.250      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.750      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.250      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.750      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.250      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.750      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.250      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78.0481-VA-18

Figure 1-21. I/O Low Voltage Distribution at 25°C

BORAM 6002 TEST SUMMARY  
 TEST 8-13 I/O LOW VOLTAGE  
 DR Terminal under test

20 APR 78

29 Samples

Test temperature -055 degrees C

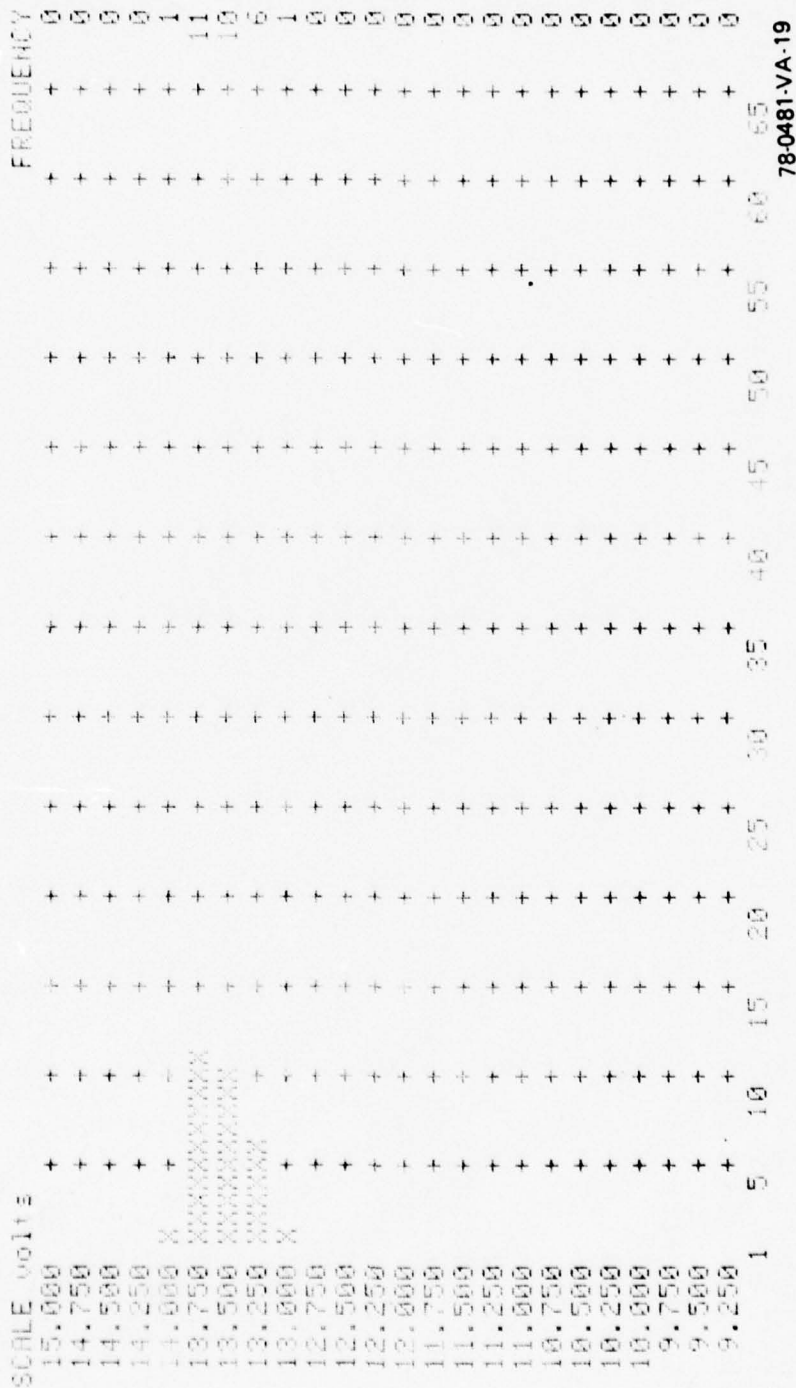


Figure 1-22. I/O Low Voltage Distribution at -55°C

#### 1.3.3.2 Output High Voltage Observations

To verify VOH (DR), VIH (DW) and VIL ( $\phi 1$  and  $\phi 2$ ) a similar strategy is used. DW is set at -1.75 volts. Both  $\phi 1$  and  $\phi 2$  are set at -14 volts. To check VOH the voltage from VCC to DR is measured when 5 milliamperes is forced out of DR.

Figures 1-23, 1-24 and 1-25 shows the VOH distributions observed at 125°C, 25°C and -55°C. The standard VOH voltage level for CMOS operated at a VDD level of +15 volts is  $(15 \times 0.7) + 10.5$  volts. The equivalent level referred to VCC is -4.5 volts. All devices in population were well above this level over the temperature range while sourcing 5 milliamperes.



[illegible]

Figure 1-23. I/O High Voltage Distribution at 125°C

BORGAM 6002 TEST SUMMARY  
 TEST 3-14 I/O HIGH VOLTAGE  
 DR Terminal under test

20 APR 78  
 Test temperature +025 degrees C

44 Samples

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-21

Figure 1-24. I/O High Voltage Distribution at 25°C

BORAM 6002 TEST SUMMARY  
 TEST 3-14 I/O HIGH VOLTAGE  
 IR Terminal under test

20 APR 78

29 Samples  
 Test temperature -55 degrees C

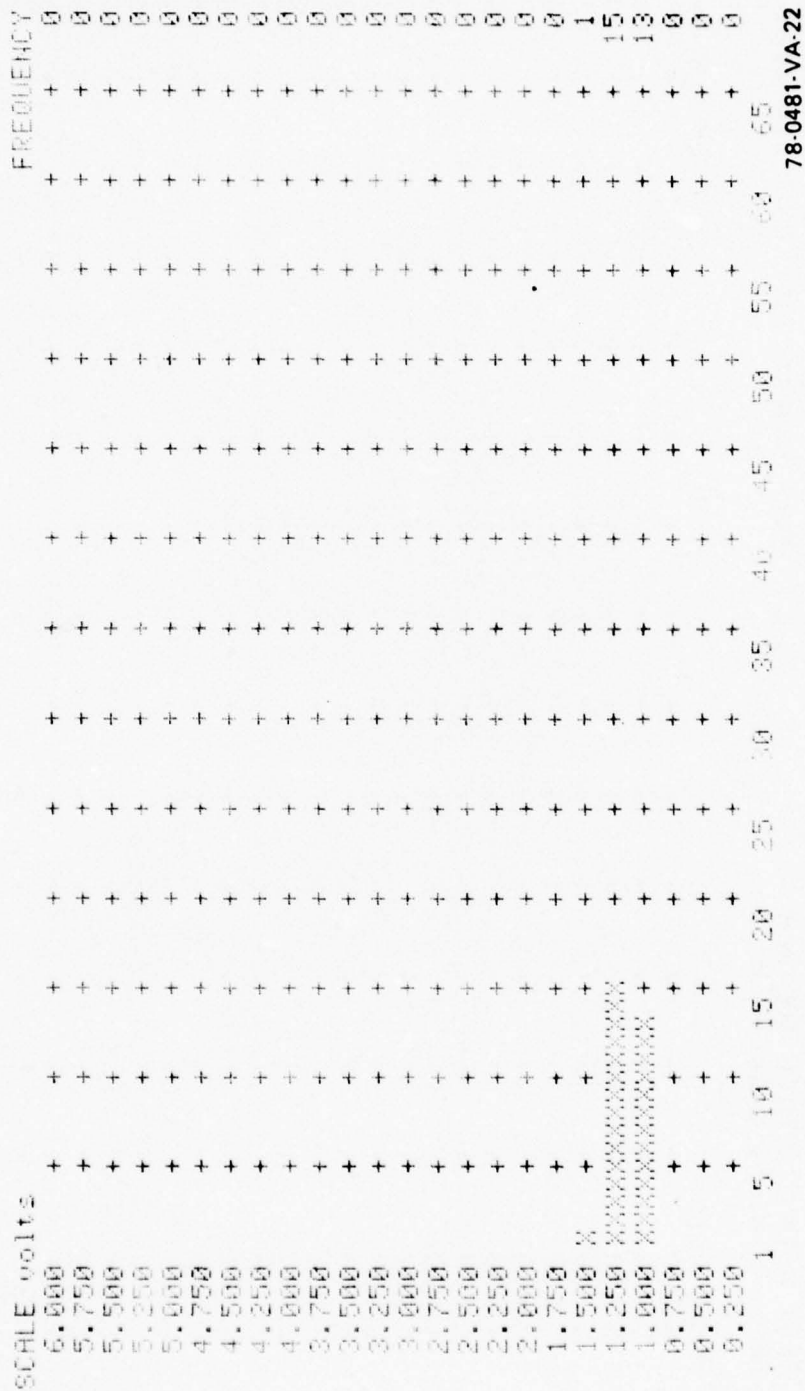


Figure 1-25. I/O High Voltage Distribution at -55°C

#### 1.3.4 Power Dissipation and Static Mode Supply Currents

Army specification SCS503 does not place limits on static mode supply currents. It does however indicate power dissipation goals. This discussion will present measured static mode supply current data, and will explain how that data is related to power dissipation.

During the electrical test of a BORAM chip, the VCC supply current is measured in six different static modes. In this context, "static mode" means that the device terminals are held at specific DC voltages, and the DC supply current is read. In the text below each current will be referred to using the symbols:

|                    |     |
|--------------------|-----|
| Deselected Standby | IDS |
| Selected Standby   | ISS |
| Read               | IR  |
| Write              | IW  |
| Chip Clear         | ICC |
| Group Clear        | IGC |
| Shift Register     | ISR |

The last current ISR is not one of the six static mode currents. It is the average current which flows into the shift register during the process of shifting data. For this analysis ISR is taken as 0.9mA from an analysis of the circuit operation.

##### 1.3.4.1 Observed Supply Current Distributions

Table 1-19 summarizes the mean supply current values observed at three temperatures. Table 1-20 shows the ratio of the current at temperature extremes to the 25°C current. ISR was initially estimated at 25°C. The ISR ratios stated in table 1-20 were assumed as a means of adjusting ISR for temperature variation.

Figure 1-26 and 1-27 show the distribution of IDS at 125°C and 25°C. The observations of IDS at -55°C were believed to be invalid because of test fixture leakage currents.

Selected standby current distributions appear in figures 1-28, 1-29 and 1-30. Read current is documented in figures 1-31, 1-32 and 1-33. The



TABLE 1-19  
BORAM 6002 STATIC SUPPLY CURRENT LEVELS

| Static Supply Current | Symbol | VCC Terminal Current |             |              |
|-----------------------|--------|----------------------|-------------|--------------|
|                       |        | -55°C<br>mA          | +25°C<br>mA | +125°C<br>mA |
| Deselected Standby    | IDS    | 0.0017               | 0.0015      | 0.0012       |
| Selected Standby      | ISS    | 14.522               | 11.025      | 9.120        |
| Read                  | IR     | 31.884               | 24.063      | 19.964       |
| Write                 | IW     | 29.053               | 21.989      | 18.414       |
| Chip Clear            | ICC    | 14.176               | 10.902      | 9.041        |
| Group Clear           | IGC    | 16.910               | 13.234      | 11.053       |
| Shift Register        | ISR    | 1.19                 | 0.9         | 0.75         |

78-0481-TA-23

TABLE 1-20  
STATIC SUPPLY CURRENT TEMPERATURE SENSITIVITY

| Static Supply Current | Symbol | Relative VCC Terminal Current |                           |
|-----------------------|--------|-------------------------------|---------------------------|
|                       |        | I (-55)/I (25)<br>Numeric     | I (125)/I (25)<br>Numeric |
| Deselected Standby    | IDS    | 1.133                         | 0.800                     |
| Selected Standby      | ISS    | 1.317                         | 0.827                     |
| Read                  | IR     | 1.325                         | 0.830                     |
| Write                 | IW     | 1.321                         | 0.837                     |
| Chip Clear            | ICC    | 1.300                         | 0.829                     |
| Group Clear           | IGC    | 1.278                         | 0.835                     |
| Shift Register        | ISR    | 1.32                          | 0.83                      |

78-0481-TA-24

EORAM 6002 TEST SUMMARY  
 TEST 3-15 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

43 Samples  
 Test temperature +125 degrees C

| SCALE microamps | 1      | 5      | 10     | 15     | 20     | 25     | 30     | 35     | 40     | 45     | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|----|----|----|----|-----------|
| 60.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 57.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 55.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 52.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 50.000 X        | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 1         |
| 47.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 45.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 42.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 40.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 37.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 35.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 32.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 30.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 27.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 25.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 22.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 20.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 17.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 15.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 12.500          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 10.000          | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 7.500           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 5.000           | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +  | +  | +  | +  | 0         |
| 2.500           | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | +  | +  | +  | +  | 42        |

78-0481-VA-25

Figure 1-26. Deselected Standby Current at 125°C

BOBAM 6002 TEST SUMMARY  
 TEST 3-15 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

44 Samples  
 Test temperature +025 degrees C

| SCALE microamps | 1                    | 5                    | 10                   | 15                   | 20                   | 25                   | 30                   | 35                   | 40                   | 45           | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|----------------------|----------------------|----------------------|----------------------|----------------------|----------------------|----------------------|----------------------|----------------------|--------------|----|----|----|----|-----------|
| 60.000 X        | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 1         |
| 57.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 55.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 52.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 50.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 47.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 45.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 42.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 40.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 37.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 35.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 32.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 30.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 27.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 25.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 22.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 20.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 17.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 15.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 12.500          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 10.000          | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 7.500           | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 5.000           | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +                    | +            | +  | +  | +  | +  | 0         |
| 2.500           | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXXXXXXXXXX | XXXXXXXXXXXX | +  | +  | +  | +  | 43        |

78-0481-VA-26

Figure 1-27. Deselected Standby Current at 25°C

BURAM 6082 TEST SUMMARY 20 APR 78 43 Samples  
 TEST 3-16 SUPPLY CURRENT Test temperature +125 degrees C  
 VCC Terminal under test

| SCALE millioamps | 1        | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|----------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.000           | XX       | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000           | XXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 10.000           | XXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 6         |
| 9.000            | XXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 8         |
| 8.000            | XXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 26        |
| 7.000            | X        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
|                  |          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

780481-VA-27

Figure 1-28. Selected Standby Current at 125°C



BCDPM 6002 TEST SUMMARY  
 TEST 3-16 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 79

44 Samples  
 Test temperature +025 degrees C

| SCALE milliwatts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 13.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 9         |
| 12.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 11.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 25        |
| 10.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 9.000            | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000            | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000            | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-28

Figure 1-29. Selected Standby Current at 25°C

BOPM 6002 TEST SUMMARY  
 TEST 3-16 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78  
 Test temperature -55 degrees C

29 Samples  
 -55 degrees C

| SCALE millivolts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 29.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 28.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 27.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 26.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 25.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 24.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 23.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 22.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 21.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 20.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 19.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 18.000 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 17.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 16.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 15.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 14.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 13.000 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 12.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 11.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 10.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 9.000            | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 8.000            | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 7.000            | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-29

Figure 1-30. Selected Standby Current at -55°C

BCRHM 6062 TEST SUMMARY  
 TEST 3-17 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

43 Samples  
Test temperature +125 degrees C

| SCALE milliamps | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 39.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 38.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 37.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 36.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 35.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 34.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 33.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 32.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 31.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 30.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000          | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000          | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 24.000          | XXX        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 23.000          | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 9         |
| 22.000          | XXXXXX     | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 5         |
| 21.000          | XXX        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 20.000          | XXXXX      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 19.000          | XXXXXXXX   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 6         |
| 18.000          | XXXXXXXX   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 6         |
| 17.000          | XXXXXX     | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 5         |
| 16.000          | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |

78-0481-VA-30

Figure 1-31. Read Current at 125°C

BURAM 6002 TEST SUMMARY 20 HPR 78 44 Samples  
 TEST 3-17 SUPPLY CURRENT Test temperature +025 degrees C  
 VCC Termini1 under test

| SCALE milliwatts | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 39.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 38.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 37.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 36.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 35.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 34.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 33.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 32.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 31.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 30.000           | XXX        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 29.000           | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 28.000           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 27.000           | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 26.000           | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 25.000           | XXXXX      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 24.000           | XXX        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 23.000           | XXXXX      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 22.000           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 21.000           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 20.000           | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 19.000           | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 18.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 17.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 16.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-31

Figure 1-32. Read Current at 25°C



BURAM 0002 TEST SUMMARY  
 TEST 3-17 SUPPLY CURRENT  
 VCC Terminal under test

20 PFR 78

29 Samples  
 Test temperature -055 degrees C

| SCALE millioamps | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 39.000 XX        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 38.000 XXXX      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 37.000 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 8         |
| 36.000 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 35.000 XX        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 34.000 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 10        |
| 33.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 32.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 31.000 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 8         |
| 30.000 XX        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 29.000 XXXX      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 28.000 XXX       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 8         |
| 27.000 XX        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 26.000 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 10        |
| 25.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000 X         | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 23.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-32

Figure 1-33. Read Current at -55°C

write current appears in figures 1-34, 1-35 and 1-36. Figures 1-37, 1-38 and 1-39 treat the chip clear current, and figures 1-40, 1-41 and 1-42 show the group clear distributions.

#### 1.3.4.2 Operating Mode Power Levels

The subject of power dissipation during circuit operation is relatively complex in that the specific operating mode and detailed timing of control signals must be considered. To clarify this issue the following discussion will relate the supply current levels measured in various static modes to the power dissipation experienced during device operation.

Before static current levels can be related to operating power, it is necessary to establish the specific operating waveform sequences involved. For the electrical test of the BORAM 6002 chip a set of operating conditions have been established. Table 1-21 relates these standard operating conditions to the static currents in terms of the dwell time in each static state. Three operating modes are treated: read mode, block write and group write.

The three operating sequences summarized in table 1-21 were selected to be similar to the conditions called for in Army specification SCS503. In each case, all 2048 bits in the chip are processed. Time is allowed for the device selection and deselection functions. Data is shifted at a 1 megahertz rate. Power dissipation can be computed from the time averaged supply current over the entire operating period.

To compute the average power for a given operating mode the time average current for the operating sequence must be formulated.

##### READ MODE

$$IRM = (4IDS + 2306ISS + 192IR + 2048ISR) / 2502$$

##### BLOCK WRITE MODE

$$IBW = (4IDS + 2435ISS + 12800IW + 1000ICC + 2048ISR) / 16239$$

##### GROUP WRITE MODE

$$IGW = (4IDS + 2434ISS + 12800IW + 16000IGC + 2048ISR) / 31238$$

BOEAM 6002 TEST SUMMARY  
 TEST 3-18 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

43 Samples  
 Test temperature +125 degrees C

| SCALE millions | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|----------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 39.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 38.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 37.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 36.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 35.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 34.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 33.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 32.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 31.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 30.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000         | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 22.000         | XXXXX      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 21.000         | XXXX       | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 20.000         | XXXX       | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 19.000         | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 10        |
| 18.000         | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 13        |
| 17.000         | XXXXXXXXX  | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 8         |
| 16.000         | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |

78-0481-VA-33

Figure 1-34. Write Current at 125°C

BORAM 6002 TEST SUMMARY  
 TEST 3-18 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

Test temperature +025 degrees C

44 Samples

SCALE millions

| SCALE millions | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|----------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 39.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 38.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 37.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 36.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 35.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 34.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 33.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 32.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 31.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 30.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000         | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 26.000         | XXXXXX     | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 5         |
| 25.000         | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 24.000         | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 23.000         | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 10        |
| 22.000         | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 11        |
| 21.000         | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 9         |
| 20.000         | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 19.000         | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 18.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000         | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000         | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |

78-0481-VA-34

Figure 1-35. Write Current at 25°C



808AH 6002 TEST SUMMARY  
 TEST 3-18 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78 29 Samples  
 Test temperature -55 degrees C

| SCALE milliamps | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 39.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 38.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 37.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 36.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 35.000 X        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 34.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 33.000 X        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 32.000 XXX      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 31.000 XXX      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 30.000 XXXXX    | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 5         |
| 29.000 XXXXXXX  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 7         |
| 28.000 XXXXXXX  | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 7         |
| 27.000 X        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 26.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000 X        | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 24.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-35

Figure 1-36. Write Current at -55°C

BORAN 6002 TEST SUMMARY  
 TEST 3-19 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

43 Samples  
 Test temperature +125 degrees C

| SCALE milliamps | 1            | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|--------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 29.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 28.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 27.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 26.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 25.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 24.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 23.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 22.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 21.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 20.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 19.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 18.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 17.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 16.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 15.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 14.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 13.000          | +            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 12.000          | X            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 11.000          | XXXXXX       | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 10.000          | XXXXXXXX     | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 9.000           | XXXXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 8.000           | XXXXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 7.000           | XXXXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-36

Figure 1-37. Chip Clear Current at 125°C

8086 6002 TEST SUMMARY  
 TEST 3-19 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

44 Samples

Test temperature +025 degrees C

| SCALE milliohms | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.000          | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000           | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-37

Figure 1-38. Chip Clear Current at 25°C

BORAN 6002 TEST SUMMARY  
 TEST 3-19 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

29 Samples  
 Test temperature -55 degrees C

SCALE milliwatts

|        | 1             | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|--------|---------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000 | +             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000 | X             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 17.000 |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000 | XX            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 15.000 | XXXXXXXXXX    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 11        |
| 14.000 | XXXXXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 14        |
| 13.000 | X             | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 12.000 |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000 |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.000 |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000  |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000  |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000  |               | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-38

Figure 1-39. Chip Clear Current at -55°C



60RAM 6002 TEST SUMMARY      20 APR 78      43 Samples  
 TEST 3-20 SUPPLY CURRENT      Test temperature +125 degrees C  
 VCC Terminal under test

| SCALE milliamps | 1        | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-----------------|----------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.000          | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000          | XXXXX    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 4         |
| 13.000          | XXXXX    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 5         |
| 12.000          | XXXXXX   | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 6         |
| 11.000          | XXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 22        |
| 10.000          | XXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 6         |
| 9.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000           | +        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-39

Figure 1-40. Group Clear Current at 125°C

BORG 0002 TEST SUMMARY  
 TEST 3-20 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

44 Samples  
 Test temperature +025 degrees C

| SCALE milliwatts | 1      | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|--------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 17.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 16.000           | XXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.000           | XXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000           | XXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.000           | XXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.000           | XXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.000           | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000            | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000            | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000            | +      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-40

Figure 1-41. Group Clear Current at 25°C

ESRM 0002 TEST SUMMARY  
 TEST 0-20 SUPPLY CURRENT  
 VCC Terminal under test

20 APR 78

29 Samples

Test temperature -55 degrees C

| SCALE millivolts | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|------------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 25.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000           | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 20.000           | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000           | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 18.000           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 11        |
| 17.000           | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 12        |
| 16.000           | XXXX       | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 15.000           | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 14.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.000           | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000            | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000            | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000            | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-41

Figure 1-42. Group Clear Current at -55°C

TABLE 1-21  
BORAM 6002 OPERATING MODES TIME SUMMARY

| Operating Sequence<br>MODE TOTAL | Dwell Time in Static Power States<br>microseconds |                  |      |       |            |             |                | Total Time<br>$\mu$ sec |
|----------------------------------|---|------------------|------|-------|------------|-------------|----------------|-------------------------|
|                                  | Preselected Standby                               | Selected Standby | Read | Write | Chip Clear | Group Clear | Shift Register |                         |
| Set-up                           | 2   | 1                | 0    | 0     | 0          | 0           | 0              | 3                       |
| Address latch                    | 0   | 128              | 0    | 0     | 0          | 0           | 0              | 128                     |
| Read & Transfer                  | 0   | 64               | 192  | 0     | 0          | 0           | 0              | 256                     |
| Empty Register                   | 0   | 2112             | 0    | 0     | 0          | 0           | 2048           | 2112                    |
| Reset                            | 2   | 1                | 0    | 0     | 0          | 0           | 0              | 3                       |
| READ MODE                        | 4   | 2308             | 192  | 0     | 0          | 0           | 2048           | 2502                    |
| Set-up                           | 2   | 1                | 0    | 0     | 0          | 0           | 0              | 3                       |
| Block erase                      | 0   | 1                | 0    | 0     | 1000       | 0           | 0              | 1001                    |
| Address latch                    | 0   | 128              | 0    | 0     | 0          | 0           | 0              | 128                     |
| Load register                    | 0   | 2112             | 0    | 0     | 0          | 0           | 2048           | 2112                    |
| Transfer & write                 | 0   | 192              | 0    | 12800 | 0          | 0           | 0              | 12992                   |
| Reset                            | 2   | 1                | 0    | 0     | 0          | 0           | 0              | 3                       |
| BLOCK WRITE                      | 4   | 2435             | 0    | 12800 | 1000       | 0           | 2048           | 16239                   |
| Set-up                           | 2   | 1                | 0    | 0     | 0          | 0           | 0              | 3                       |
| Address latch                    | 0   | 32               | 0    | 0     | 0          | 0           | 0              | 32                      |
| Group erase                      | 0   | 96               | 0    | 0     | 0          | 16000       | 0              | 16096                   |
| Load register                    | 0   | 528              | 0    | 0     | 0          | 0           | 512            | 528                     |
| Transfer & write                 | 0   | 48               | 0    | 3200  | 0          | 0           | 0              | 3248                    |
| Load register                    | 0   | 528              | 0    | 0     | 0          | 0           | 512            | 528                     |
| Transfer & write                 | 0   | 48               | 0    | 3200  | 0          | 0           | 0              | 3248                    |
| Load register                    | 0   | 528              | 0    | 0     | 0          | 0           | 0              | 528                     |
| Transfer & write                 | 0   | 48               | 0    | 3200  | 0          | 0           | 0              | 3248                    |
| Load register                    | 0   | 528              | 0    | 0     | 0          | 0           | 512            | 528                     |
| Transfer & write                 | 0   | 48               | 0    | 3200  | 0          | 0           | 0              | 3248                    |
| Reset                            | 2   | 1                | 0    | 0     | 0          | 0           | 0              | 3                       |
| GROUP WRITE                      | 4   | 2434             | 0    | 12800 | 0          | 16000       | 2048           | 31238                   |

78-0481-TA-42



The respective power levels at a nominal VCC to VGG voltage of 30 volts would be

$$\text{PRM} = 30\text{IRM} \quad \text{PBW} = 30\text{IBW} \quad \text{PGW} = 30\text{IGW}$$

A computer program was written to accept the static current values given in table 1-19 and use the average current equations to compute power. The results are listed in table 1-22.

#### 1.4 TEST STRUCTURE OBSERVATIONS

A series of five measurements in the characterization program are made on nodes that are not normally accessible after packaging. Table 1-23 presents the mean values obtained from sample populations at 125°C, 25°C and -55°C.

This information was obtained from subsets of the samples used for the integrated circuit data presented earlier in this report. The computer data reduction program was used to eliminate grossly defective samples from the populations.

TABLE 1-22  
BORAM 6002 OPERATING POWER LEVELS

| Operating Mode | Average Power Dissipation |            |             |
|----------------|---------------------------|------------|-------------|
|                | -55°C<br>mW               | 25°C<br>mW | 125°C<br>mW |
| READ           | 504.2                     | 382.3      | 316.5       |
| BLOCK<br>WRITE | 783.0                     | 593.1      | 496.0       |
| GROUP<br>WRITE | 653.3                     | 501.2      | 419.0       |

78-0481-TA-43

TABLE 1-23  
OBSERVED TEST STRUCTURE CHARACTERISTICS

| Measured<br>Parameter                          | Observed Mean Voltage |               |                | Temperature Sensitivity           |                                   |
|--|-----------------------|---------------|----------------|-----------------------------------|-----------------------------------|
|  | -55°C<br>Volts        | 25°C<br>Volts | 125°C<br>Volts | $\frac{V(-55)}{V(25)}$<br>Numeric | $\frac{V(125)}{V(25)}$<br>Numeric |
| Nonmemory Transistor<br>Threshold              | -2.462                | -2.395        | -2.333         | 1.028                             | 0.974                             |
| Memory Transistor High<br>Conduction Threshold | -2.493                | -2.467        | -2.430         | 1.011                             | 0.985                             |
| Memory Transistor Low<br>Conduction Threshold  | -13.107               | -13.032       | -12.732        | 1.006                             | 0.977                             |
| Memory Substrate<br>Voltage High               | -4.083                | -3.500        | -2.176         | 1.168                             | 0.622                             |
| Memory Substrate<br>Voltage Low                | -25.583               | -26.068       | -26.033        | 0.981                             | 0.999                             |

78 0481 TA 44

Figures 1-46 to 148 show the distribution of nonmemory transistor threshold voltages. The distribution of memory transistor high conduction thresholds are shown in figures 1-49, 1-50 and 1-51; and low conduction thresholds are shown in figures 1-52, 1-53 and 1-54. The high voltage level of the memory substrate is displayed in figures 1-52, 1-53 and 1-54. Memory substrate low voltages during erase are shown in figures 1-55 to 1-57.

BURAM 6002 TEST SUMMARY  
 TEST 5-01 NONMEMORY VT  
 VHM Terminal under test

20 APR 78  
 Test temperature +125 degrees C

38 Samples

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 1         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 35        |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-45

Figure 1-43. Nonmemory Transistor Threshold at 125°C



BORAN 6002 TEST SUMMARY  
 TEST 5-01 NONMEMORY VT  
 VHM Terminal under test

20 APR 78

29 Samples  
 Test temperature +025 degrees C

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 35        |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-46

Figure 1-44. Nonmemory Transistor Threshold at 25°C

BORAM 6002 TEST SUMMARY  
 TEST 5-01 NONMEMORY VT  
 VNM Terminal under test

10 APR 78  
 Test temperature -55 degrees C

23 Samples

SCALE volts

| SCALE volts | 1              | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|----------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.750       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.500       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.250       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.000       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.750       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.500       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.250       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.000       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.750       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.500       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.250       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.000       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.750       | XXXXXX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.500       | XXXXXXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.250       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.000       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.750       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.500       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.250       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.000       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.750       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.500       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.250       | +              | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-47

Figure 1-45. Nonmemory Transistor Threshold at -55°C

BORAM 6002 TEST SUMMARY  
 TEST 5-02 MEMORY V1  
 VHNC Terminal under test

29 APR 78  
 Test temperature +125 degrees C

38 Samples

SCALE volts

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 3         |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 5         |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-48

Figure 1-46. Memory Transistor High Conduction Threshold at 125°C

BURAN 6002 TEST SUMMARY  
 TEST 5-02 MEMORY VT  
 VMHC Terminal under test

20 APR 78  
 Test temperature 1025 degrees C

39 Samples

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-49

Figure 1-47. Memory Transistor High Conduction Threshold at 25°C



BORAM 6002 TEST SUMMARY  
 TEST 5-02 MEMORY VT  
 VMHC Terminal under test

20 APR 78

23 Samples  
Test temperature -85.5 degrees C

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 15        |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-50

Figure 1-48. Memory Transistor High Conduction Threshold at -55°C

BURAM 6002 TEST SUMMARY  
 TEST 5-03 MEMORY VT  
 VMLC Terminal under test

20 APR 78

38 Samples  
 Test temperature +125 degrees C

| SCALE volts | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 16.000      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.500      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 15.000      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.500      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 14.000      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 13.500      | XXXXXXX    | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 11        |
| 13.000      | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 17        |
| 12.500      | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 12.000      | XX         | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 11.500      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 11.000      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.500      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 10.000      | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 9.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 8.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 7.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 6.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78.0481-VA-51

Figure 1-49. Memory Transistor Low Conduction Threshold at 125°C

BORAM 6002 TEST SUMMARY  
 TEST 5-03 MEMORY VT  
 VMLC Terminal under test

20 APR 78  
 Test temperature +025 degrees C

39 Samples

| SCALE volts | 1      | 5      | 10     | 15     | 20     | 25     | 30     | 35     | 40     | 45     | 50     | 55     | 60     | 65     | FREQUENCY |
|-------------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|-----------|
| 16.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 15.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 15.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 14.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 14.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 13.500      | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | 20        |
| 13.000      | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | 18        |
| 12.500      | X      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 1         |
| 12.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 11.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 11.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 10.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 10.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 9.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 9.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 8.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 8.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 7.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 7.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 6.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 6.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 5.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 5.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 4.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |

78-0481-VA-52

Figure 1-50. Memory Transistor Low Conduction Threshold at 25°C

BORAM 6002 TEST SUMMARY  
 TEST 5-03 MEMORY VT  
 VMLC Terminal under test

20 APR 78  
 Test temperature -55 degrees C

20 Samples  
 -055 degrees C

| SCALE volts | 1      | 5      | 10     | 15     | 20     | 25     | 30     | 35     | 40     | 45     | 50     | 55     | 60     | 65     | FREQUENCY |
|-------------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|--------|-----------|
| 16.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 15.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 15.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 14.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 14.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 13.500      | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | 18        |
| 13.000      | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | XXXXXX | 5         |
| 12.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 12.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 11.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 11.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 10.500      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 10.000      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 9.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 9.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 8.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 8.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 7.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 7.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 6.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 6.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 5.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 5.000       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |
| 4.500       | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | +      | 0         |

78-0481-VA-53

Figure 1-51. Memory Transistor Low Conduction Threshold at -55°C



BORAM 6002 TEST SUMMARY  
 TEST 5-04 MEMORY SUBSTRATE  
 SUBH Termino1 under test

20 APR 78  
 Test temperature +125 degrees C

38 Samples

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.750       | X | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.500       | X | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.250       | X | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.000       | X | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

780481-VA-54

Figure 1-52. Memory Substrate Voltage High at 125°C

BORAM 6002 TEST SUMMARY  
 TEST 5-04 MEMORY SUBSTRATE  
 SUCH Terminal under test

20 APR 78  
 Test temperature +025 degrees C

39 Samples

| SCALE volts | 1          | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|------------|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.750       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.250       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 5.000       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.750       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.500       | +          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.250       | XXX        | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 4.000       | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.750       | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 10        |
| 3.500       | XXXXXXXXXX | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.250       | XXXX       | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 3.000       | XXXXX      | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.750       | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.500       | X          | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 2.000       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.750       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.500       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.250       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 1.000       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.750       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.500       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 0.250       |            | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

78-0481-VA-55

Figure 1-53. Memory Substrate Voltage High at 25°C

BORAM 6002 TEST SUMMARY  
 TEST 5-04 MEMORY SUBSTRATE  
 SUBH Terminal under test

20 APR 78  
 Test temperature -55 degrees C

20 Samples

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 6.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 5.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 4.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 3.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 2.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 1.000       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.750       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.500       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 0.250       | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-56

Figure 1-54. Memory Substrate Voltage High at -55°C

AD-A058 773

WESTINGHOUSE DEFENSE AND ELECTRONIC SYSTEMS CENTER B--ETC F/G 9/1  
MNOS BORAM MANUFACTURING METHODS AND TECHNOLOGY PROJECT.(U)

JUL 78 J E BREWER

DAAB07-76-C-0048

UNCLASSIFIED

78-0481

DELET-TR-76-0048-6

NL

2 of 2  
AD  
A058 773



END

DATE  
FILMED

-11-78

DDC



BORAN 6002 TEST SUMMARY  
 TEST 5-05 MEMORY SUBSTRATE  
 SUBL Terminal under test

20 APR 78  
 Test temperature +125 degrees C

38 Samples  
 125 degrees C

| SCALE volts | 1            | 5            | 10           | 15           | 20           | 25           | 30           | 35           | 40           | 45           | 50           | 55           | 60           | 65           | FREQUENCY |
|-------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|--------------|-----------|
| 30.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 29.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 29.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 28.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 28.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 27.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 27.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 26.500      | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | 22        |
| 26.000      | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | XXXXXXXXXXXX | 16        |
| 25.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 25.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 24.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 24.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 23.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 23.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 22.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 22.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 21.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 21.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 20.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 20.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 19.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 19.000      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |
| 18.500      | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | +            | 0         |

78-0481-VA-57

Figure 1-55. Memory Substrate Voltage Low at 125°C

BORAM 6062 TEST SUMMARY  
 TEST 5-05 MEMORY SUBSTRATE  
 SUBL Terminal under test

20 APR 78

39 Samples

Test temperature +625 degrees C

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 29.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 28.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 27.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 26.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 2         |
| 26.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 21        |
| 25.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 16        |
| 25.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 24.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 23.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 22.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 21.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 20.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 19.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |
| 18.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | 0         |

780481-VA-58

Figure 1-56. Memory Substrate Voltage Low at 25°C

BURAM 6002 TEST SUMMARY  
 TEST 5-05 MEMORY SUBSTRATE  
 SUBL Terminal under test

20 APR 78  
 Test temperature -55 degrees C

23 Samples  
 -055 degrees C

| SCALE volts | 1 | 5 | 10 | 15 | 20 | 25 | 30 | 35 | 40 | 45 | 50 | 55 | 60 | 65 | FREQUENCY |
|-------------|---|---|----|----|----|----|----|----|----|----|----|----|----|----|-----------|
| 30.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 29.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 29.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 28.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 28.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 27.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 27.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 26.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 26.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 25.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 25.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 24.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 24.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 23.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 23.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 22.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 22.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 21.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 21.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 20.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 20.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 19.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 19.000      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |
| 18.500      | + | + | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +  | +         |

78-0481-VA-59

Figure 1-57. Memory Substrate Voltage Low at -55°C

### 1.5 PRODUCTION ACTIVITY

During the reporting period production learning for the BORAM 6002 chip has continued, and yields have risen significantly. Table 1-24 compares current experience with the initial chip fabrication results.

The MM&T project began work with the 6000C chip, and achieved a yield of about 1.5 die per wafer start. The initial experience with the 6002 chip was about 11 die per two-inch wafer. Current results exceed 33 die per wafer.

Conservative mathematical yield models predict average probe yields of 0.38 for the 6002 chip. Current average experience is 0.22. The highest yield observed was 87 die per wafer, or about 0.45.

TABLE 1-24  
BORAM 6002 YIELD GROWTH

| Yield Component | Symbol | Yield Experience    |                     |
|-----------------|--------|---------------------|---------------------|
|                 |        | 2nd Quarter<br>1977 | 1st Quarter<br>1978 |
| Process Yield   | $Y_W$  | 0.63                | 0.77                |
| Probe Yield     | $Y_T$  | 0.09                | 0.22                |
| Overall Yield   | $Y$    | 0.06                | 0.17                |

78 0481 TA-60



## 2. CONCLUSIONS

The BORAM 6002 chip has been brought to the stage of maturity necessary for low risk manufacture. Production learning trends are firmly established, and costs can be expected to reduce as volume levels increase. All the ground work necessary for pilot production has been completed.

### 3. PROGRAM FOR NEXT INTERVAL

The primary task during the next period is completion and delivery of the confirmatory sample hybrids, and initiation of the pilot run.

#### 4. PUBLICATIONS AND REPORTS

During the reporting period there were no publications derived directly from this contract effort.

## 5. IDENTIFICATION OF TECHNICIANS

The following key engineers and management personnel were employed on the BORAM manufacturing methods project from January to March of 1978.

| <u>Technician</u> | <u>Manhours</u> |
|-------------------|-----------------|
| R. Crebs          | 169             |
| P. Smith          | 8               |
| C. Waldvogel      | 8               |

Mr. K. H. Gibbs has replaced J. L. Hetrick as the program financial manager.



APPENDIX A  
TECHNICAL REQUIREMENT SCS-503

**Metal Nitride Oxide Semiconductor (MNOS) Integrated  
Circuits for Block Oriented Random Access Memory (BORAM)**

**1. SCOPE**

1.1 This specification covers the detailed requirements for metal nitride oxide semiconductor integrated circuit chips for use in the manufacture of block oriented random access memory modules.

**2. APPLICABLE DOCUMENTS**

2.1 The following documents of the issue in effect on the date of invitation for bid, form part of this specification to the extent specified herein.

**SPECIFICATION**

**Military**

MIL-P-11268

Parts, Materials and Processes  
Used in Electronic Equipment

MIL-M-38510

Microcircuits, General Specification for

(Copies of documents required by contractors in connection with specific procurement functions should be obtained from the procuring activity or as directed by the contracting officer. Both the title and number or symbol should be stipulated when requesting copies.)

**3. REQUIREMENTS**

3.1 MNOS BORAM Chip Functional Description. The MNOS BORAM chip covered by this specification shall be a 2048 word by 1 bit memory array, and shall have the following features:

- o Nonvolatile electrically alterable memory for implementation of memory systems.
- o 2048 bits organized as 2048 by 1 or 1024 x 2
- o Sequential Input Data Format
- o Internal serial to parallel transfer to provide at least 1.0 Mhz data rate with a 26 KHz row decode rate.

- o Block clear of 2048 bits.
- o Data I/O 15 volt CMOS compatible.
- o Address Inputs and Clock Phases 15 volt CMOS compatible.
- o Chip select with P-channel compatible levels.
- o Write and clear address controlled by chip select (CS).
- o Power strobed by chip select to minimize standby power.
- o Output "Tri-state" to permit "wire-or" tie.
- o Memory expansion simplified by chip select logic.
- o Charge enhancement read to extend period of nonvolatile memory.
- o Operating temperature  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ .

3.2 Physical Characteristics. The BORAM chips shall be fabricated using silicon wafer and P-type metal oxide semiconductor (PMOS) technology in addition to the metal nitride oxide semiconductor (MNOS) techniques. The BORAM chip shall have maximum dimensions of 0.250 inches by 0.250 inches.

3.3 Memory Characteristics. The BORAM chip memory characteristics shall be as follows:

3.3.1 Operation. Operation of the BORAM chip is defined as: the sequencing of controls to clear the chip and write in a digital data sequence, and the sequencing of controls to read out the digital data from the chip and compare it to the input data sequence. Failure of any data bit to compare constitutes failure of operation.

3.3.2 Capacity. The BORAM chip shall have a capacity of 2048 bits of data. This data shall be accessed, for reading or writing, by a serial shift register on the BORAM chip.

3.3.3 Retention. The BORAM chip shall be capable of retaining the data for at least 4000 hours. For purposes of testing this characteristic can be verified by extrapolation.

3.3.4 Electrical Alterable. The BORAM chip shall be capable of being cleared and new data written in and verified electrically.

3.3.5 Read. The BORAM chip shall exhibit no detectable deterioration of signal levels after being read ten times.

3.3.6 Non-Volatile. The BORAM chip shall retain the data upon removal of electric power.

3.4 Chip Select. The BORAM chip shall be so designed that the chip select signal shall enable all other chip functions. Whenever the chip select is a logic zero, the chip with power supplies attached shall draw minimum power and shall be unaffected by any other signals. When the chip select is a logic one the chip shall be active and shall respond to all other signals.

3.5 Electrical Ratings. The BORAM chip shall operate as specified with power supply variations of +1% and signal input variations of +1%.

3.5.1 Power Supplies. The BORAM chip shall have the following power supplies:

|     |   |           |                                 |
|-----|---|-----------|---------------------------------|
| VCC | = | +15 volts | (most positive voltage)         |
| CL  | = | 0 volts   | (intermediate negative voltage) |
| VGG | = | -15 volts | (most negative voltage)         |

3.5.2 Signals. The electrical signals to the BORAM chip shall be as follows:

3.5.2.1 Signal Descriptions. The signals to the BORAM chip are given in the following subparagraphs.

3.5.2.1.1 Address Lines. The BORAM chip shall have no more than six address lines (A0-A5). These lines shall serve to define the row or data bits to be read or written.

3.5.2.1.2 Access Enable. The access enable (AE) signal shall enable the address select into the memory array area of the chip for purposes of reading or writing data.

3.5.2.1.3 Clocks. The two clock signals ( $\phi 1$ ,  $\phi 2$ ) shall cause the sequencing of the on chip shift register to cause data to be transferred into or out of the chip.

3.5.2.1.4 Clear. The clear signal (CL) shall cause the two transistor cells in the BORAM chip to be reset so that data can be written into the chip.

3.5.2.1.5 Transfer. The transfer signal (TR) shall cause the transfer of data into and out of the shift register in a parallel form to the memory section of the chip.

3.5.2.1.6 Memory Write. The memory write signal (MW) shall cause a row of data to be written into memory.

3.5.2.1.7 Data Input. The data input line (DW) shall provide input data to the shift register.

3.5.2.1.8 Data Output. The output line (OR) shall represent the data output of the shift register. Whenever chip select is a logic zero, the output shall be disabled and shall present an impedance greater than 500 ohms.



3.5.2.2 Signal Levels. The voltage levels for logic one and logic zero for the signals to the BORAM chip shall be as follows:

| <u>SIGNAL</u>   | <u>LOGIC ZERO</u> | <u>LOGIC ONE</u> |
|---|-------------------|------------------|
| A1/j, $\overline{AE}$ , $\overline{TR}$ , $\overline{MW}$ | VCC - 10.5        | VCC - 2.0        |
| $\emptyset 1$ , $\emptyset 2$                             | VCC - 14.25       | VCC - 2.0        |
| CL  | VCC - 14.85       | VCC - 2.0        |
| CS  | VCC - 34.65       | VCC - 2.0        |
| DW  | VCC - 10.5        | VCC - 2.0        |
| DR  | VCC - 10.5        | VCC - 4.5        |

### 3.6 Electrical Characteristics.

|                               |                               |
|-------------------------------|-------------------------------|
| Block Read Cycle Time:        | <2.5 msec per 2048 bits       |
| Data Rate:                    | >1.0 MHz                      |
| Memory Clear Pulsewidth:      | 1000 usec max per write cycle |
| Memory Write Pulsewidth:      | 200 usec max                  |
| Block Write Cycle Time:       | <16 msec per 2048 bits        |
| First Bit Access Time:        | <5 usec                       |
| Read Mode Power Dissipation:  | <670 mW at 25°C               |
| Write Mode Power Dissipation: | <700 mW at 25°C               |
| Standby Power Dissipation:    | <1 mW                         |

3.7 Mounting. The BORAM chips shall be mounted in hybrid packages. Sixteen (16) MNOS BORAM IO chips shall be mounted in each hybrid package to permit testing individually or of the entire assembly.

3.8 Environmental Requirements. The MNOS BORAM chip as mounted in the hybrid package shall comply with the requirement of paragraph 3 and in particular operation as defined in 3.3.1, of this specification after being subjected to mechanical shock, vibration, constant acceleration and high temperature environments. (See 4.5 Tables 1 and 2).

3.9 Process Conditions. All units shall be process conditioned. (see table 1).

#### 4. QUALITY ASSURANCE PROVISIONS

4.1 Responsibility for Inspection. Unless otherwise specified in the contract or purchase order, the supplier is responsible for the performance of all inspection requirements as specified herein. Except as otherwise specified in the contract or order, the supplier may use his own or any other facilities suitable for the performance of the inspection requirements specified herein, unless disapproved by the Government. The Government reserves the right to perform any of the inspections set forth in the specification where such in specifications are deemed necessary to assure supplies and services conform to prescribed requirements.

4.2 Classification of Inspection. Inspection shall be classified as follows:

- (a) First Article inspection (does not include preparation for delivery (see 4.3).
- (b) Quality conformance inspection (see 4.4)

4.2.1 Process Conditioning. Confirmatory sample units shall be process conditioned per Table 1. Pilot run units do not require stabilization bake and temperature cycle, but shall otherwise be conditioned per Table 1. Subsequent production shall be conditioned per Table 1.

4.3 Confirmatory Sample Inspection. Confirmatory sample testing shall consist of the tests specified in Table 2. All confirmatory sample units shall be subjected to these tests.

4.4 Quality Conformance Inspection. The contractor is not required to perform a Quality Conformance inspection on pilot run production. Subsequent production shall be inspected per Table 2.

4.5 Test Plan. The contractor prepared, Government - approved test plan shall contain:

- (a) An operational test method to show that the BORAM chips as mounted in hybrid packages, satisfactorily meet the requirements of paragraph 3, and in particular operation as defined in paragraph 3.3.1.
- (b) Time schedule and sequence of examinations and tests.
- (c) A description of the method and procedures.
- (d) Program of any automatic tests including flow charts and block diagrams.

## 5. PREPARATION FOR DELIVERY

5.1 Preparation for delivery shall be in accordance with the best commercial practice.

TABLE 1 PROCESS CONDITIONING REQUIREMENTS

| Conditioning Operations                                | MIL-STD 883<br>Test Method | Description   |
|--|----------------------------|---|
| Stabilization Bake                                     | 1008.1<br>Condition C      | 24 hour bake at<br>150°C with no end<br>point measurements.   |
| Temperature Cycle                                      | 1010.1<br>Condition B      | 10 cycles required<br>with no end point<br>measurements,      |
| Pre Burn-In 25°C<br>Electrical Test                    | Does Not<br>Apply          | Test must conform to<br>SCS-503 paragraphs<br>3 and 4.5.      |
| Burn-In Test<br>125°C Ambient                          | 1015.1<br>Condition C      | Steady-state, power<br>and reverse bias for<br>160 hours.     |
| Post Burn-In<br>25°C, 125°C, -55°C<br>Electrical Tests | Does not<br>Apply          | Tests must conform to<br>paragraphs 3 and 4.5.<br>of SCS-503. |

TABLE 2 GROUP C TESTS (NOTE 1)

| EXAMINATION OR TEST      | MIL-STD 883<br>TEST METHOD | FAILURES<br>ALLOWED |
|--------------------------|----------------------------|---------------------|
| <u>Subgroup 1</u>        |                            |                     |
| Mechanical Shock         | 2002<br>Condition B        | 1                   |
| Variable Vibration       | 2007<br>Condition A        | 1                   |
| Constant Acceleration    | 2001<br>Condition B        | 1                   |
| <u>Subgroup 2</u>        |                            |                     |
| High Temperature Storage | 1008<br>Condition C        | 0                   |

NOTE 1 - End point electrical tests are required after each test per method specified in paragraph 4.5.



APPENDIX B  
DISTRIBUTION LIST

| <u>Addressee</u>   | <u>Qty</u> | <u>Addressee</u>   | <u>Qty</u> |
|--|------------|--|------------|
| Defense Documentation Center<br>ATTN: DDC-TCA<br>Cameron Station (Bldg 5)<br>Alexandria, VA 22314              | 12         | Chief, Intell Matl Dev Office<br>Electronic Warfare Lab.<br>USAECOM<br>Fort Holabird, MD 21219                             | 1          |
| Director<br>National Security Agency<br>ATTN: TDL<br>Fort George G. Meade, MD<br>20755                         | 1          | Air Force Avionics Lab<br>ATTN: AFAL/DOT, STINFO<br>Wright-Patterson AFB, OH<br>45433                                      | 1          |
| Ofc, Asst Sec of the Army (R&D)<br>ATTN: Asst for Research<br>Room 3E379, The Pentagon<br>Washington, DC 20310 | 1          | Office of Naval Research<br>Code 427<br>Arlington, VA 22217  | 1          |
| Commanding General<br>US Army Material Command<br>ATTN: DRCMT<br>5001 Eisenhower Bldg.<br>Alexandria, VA 22304 | 1          | Commanding General<br>US Army Material Command<br>ATTN: DRCMA-EE<br>5001 Eisenhower Blvd<br>Alexandria, VA 22304           | 1          |
| Mr. William Reller<br>AMES Bldg, Room 516<br>Washington, DC 20505  | 1          | CG, US Army Missile Command<br>Redstone Scientific Info Ctr<br>ATTN: Chief, Document Section<br>Redstone Arsenal, AL 35809 | 1          |
| Commanding Officer<br>USA Satellite Comm Agency<br>ATTN: AMCPM-SC-3<br>Fort Monmouth, NJ 07703                 | 1          | CO, USA Foreign Science Div<br>ATTN: AMXST CE Division<br>220 Seventh St., NE<br>Charlottesville, VA 22901                 | 1          |
| US Army Research Office -<br>Durham<br>ATTN: CRDARD-IP<br>Box CM, Duke Station<br>Durham, NC 27706             | 1          | US Army Liaison Office<br>MIT - Lincoln Lab, Room A-210<br>P.O. Box 73<br>Lexington, MA 02173                              | 1          |

| <u>Addressee</u>   | <u>Qty</u> | <u>Addressee</u>  | <u>Qty</u> |
|--|------------|---|------------|
| US Army Research Ofc - Durham<br>ATTN: Dr. Robert J. Lontz<br>Box CM, Duke Station<br>Durham, NC 27706                                       | 1          | International Business Machine Corp<br>Research Division<br>ATTN: Dr. F. Bill<br>P.O. Box 218<br>Yorktown Heights, NY 10598 | 1          |
| USA Security Agency<br>ATTN: IARD<br>Arlington Hall Station<br>Bldg 420<br>Arlington, VA 22212   | 1          | Dr. Gordon E. Moore<br>Intel Corporation<br>3065 Bowers Road<br>Santa Clara, CA 95951                                       | 1          |
| Commander<br>US Army Electronics Command<br>ATTN: DRSEL-PP-I-PI-1<br>(Mr. D. Biser)<br>Fort Monmouth, NJ 07703                               | 3          | Director<br>US Army Adv Matl Concepts Agcy<br>ATTN: AMXAM<br>Washington, DC 20315   | 1          |
| Commanding General<br>US Army Materiel Command<br>ATTN: AMCRD-R<br>5001 Eisenhower Blvd<br>Alexandria, VA 22304                              | 1          | Commanding General<br>US Army Missile Command<br>ATTN: AMSMI-RFG (Mr. N. Bell)<br>Redstone Arsenal, AL 35809                | 1          |
| Commanding Officer<br>Harry Diamond Laboratories<br>ATTN: AMXDO-RCB<br>(Mr. Nemarich)<br>Washington, DC 20438                                | 1          | Advisory Gp on Electron Devices<br>201 Varick Street, 9th Floor<br>New York, NY 10014                                       | 1          |
| Autonetics<br>Division of North American<br>Rockwell<br>ATTN: Dr. G.R. Pulliam<br>P.O. Box 4173<br>3370 Miraloma Avenue<br>Anaheim, CA 92803 | 1          | Sperry Rand Research Center<br>ATTN: Dr. H. Van De Vaart<br>100 North Road<br>Sudbury, MA 01776                             | 1          |
| Westinghouse Electric Corp<br>Research and Development Center<br>ATTN: Dr. J. DeKlerk<br>Beulah Road<br>Pittsburgh, PA 15235                 | 1          | Mr. R. Weglein<br>Hughes Research Laboratories<br>3011 Malibu Canyon Road<br>Malibu, CA 09265                               | 1          |
|  |            | Stanford Research Institute<br>ATTN: Dr. A. Bahr<br>Menlo Park, CA 94025  | 1          |

| <u>Addressee</u>   | <u>Qty</u> | <u>Addressee</u>  | <u>Qty</u> |
|--|------------|---|------------|
| Director<br>Defense Communications Agency<br>Technical Library Center<br>Code 205 (P. A. Tolovi)<br>Washington, DC 20305 | 1          | Mr. James Doyle<br>General Electric Defense<br>Electronics Division<br>Utica, NY 13503              | 1          |
| Mr. Jack Kilby<br>5924 Royal Lane<br>Suite 150<br>Dallas, TX 75230   | 1          | Dr. Andrew Tickl<br>Nitron Corporation<br>10420 Bubb Road<br>Cupertino, CA 95014                    | 1          |
| Institute Defense Analysis<br>Arlington, VA 22209  | 1          | Dr. Patrick J. Vail<br>RADC/ETSD, Stop 30<br>Hansom AFB, MA 01731                                   | 1          |
| Commander<br>Harry Diamond Laboratories<br>ATTN: Mr. A.J. Baba<br>2800 Powder Mill Rd.<br>Adelphi, MD 20783              | 1          | Naval Electronic Laboratory Ctr<br>ATTN: Mr. C.E. Holland, Jr.<br>Code 4300<br>San Diego, CA 92152  | 1          |
| Dr. Gerald B. Herzog<br>Solid State Technology Center<br>RCA David Sarnoff Research Ctr<br>Princeton, NJ 08540           | 1          | Commander<br>RADC<br>ATTN: RBRM/Mr. J. Brauer<br>Griffiss AFB, NY 13441                             | 1          |
| Mr. Harold D. Toombs<br>Texas Instruments, Inc.<br>P.O. Box 5012<br>Dallas, TX 75222                                     | 1          | Dr. George E. Smith<br>Bell Telephone Laboratories, Inc<br>Room 2A323<br>Murray Hill, NJ 07974      | 1          |
| AFAL/TEA<br>ATTN: Fritz Schuermeyer<br>Wright-Patterson AFB, OH<br>45433   | 1          | Commander<br>US Army Electronics Command<br>ATTN: DRSEL-TL-ID (H. Mette)<br>Fort Monmouth, NJ 07703 | 2          |
| Naval Ordnance Lab<br>ATTN: Mr. Frederick E. Warnock<br>White Oak, MD 20910  | 1          | Naval Air Development Center<br>ATTN: Roman Fedorak Code 2071<br>Warminster, PA 19067               | 1          |
| COMM/ADP Lab, ECOM<br>ATTN: DRSEL-NL-BP<br>Mr. David Haratz<br>Fort Monmouth, NJ 07703                                   | 1          | COMM/ADP Lab, ECOM<br>ATTN: DRSEL-NL-BP-1<br>Mr. David R. Hadden, Jr.<br>Fort Monmouth, NJ 07703    | 1          |



| <u>Addressee</u>   | <u>Qty</u> | <u>Addressee</u>   | <u>Qty</u> |
|--|------------|--|------------|
| Honeywell Avionics Division<br>ATTN: Richard L. Wiker<br>13350 US Highway 19<br>St. Petersburg, FA 33733                     | 1          | Director Night Vision Lab<br>USAECOM<br>ATTN: DRSEL-NV-II<br>Mr. Joseph Martino  | 1          |
| Mr. F. B. Micheletti<br>Electronics Research Division<br>Rockwell International<br>3370 Miraloma Avenue<br>Anaheim, CA 92803 | 1          | Fort Belvoir, VA 22060   |            |
| Mr. W. H. Dodson<br>Sandia Laboratories<br>Div 2116<br>Albuquerque, NM 87115   |            | Naval Research Laboratory<br>ATTN: Dr. David F. Barbe<br>Code 5260<br>4555 Overlook Ave., SW<br>Washington, DC 20375                 | 1          |
| Carmine J. Salvo<br>Rome Air Development Center<br>Griffiss AFB, NY 13441  | 1          | Mr. Merton Horne MS UIX26<br>Sperry Univac Defense Systems<br>Division<br>P. O. Box 3525<br>St. Paul, MN 55165                       | 1          |
| Dr. Barry Dunbridge<br>TWR Systems Group<br>One Space Park<br>Redondo Beach, CA 90278  | 1          | Fairchild Semiconductor Research<br>& Development Laboratory<br>ATTN: Dr. James M. Early<br>4001 Miranda Ave.<br>Palo Alto, CA 10504 | 1          |
| Naval Research Laboratories<br>ATTN: L. Palkuti, Code 5216<br>Washington, DC 20375   | 1          | Commander<br>Air Force Avionics Lab AVTM<br>ATTN: Dr. Ronald Belt<br>Wright-Patterson AFB, OH 45433                                  | 1          |
| General Electric Co.<br>Research & Development Center<br>ATTN: Dr. J. J. Tiemann<br>Schenectady, NY 12305                    | 1          | Naval Air Test Center<br>ATTN: SY-43/SETD<br>Mr. James McIntyre<br>Patuxent River, MD 20670  | 1          |
| Marketing Department<br>Bell-Northern Research Ltd.<br>P. O. Box 3511, Station C<br>Ottawa, Canada K1Y 4H7                   | 1          | Dr. Yukon Hsia<br>Actron<br>700 Royal Oaks Drive<br>Monrovia, CA 91016   | 1          |
| Reliability Analysis Center<br>RADC (RBRAC)<br>ATTN: I. L. Krulac<br>Griffiss AFB, NY 13441                                  | 1          | John Reekstin, Mail Stop HA-31<br>Rockwell International<br>P. O. Box 3105<br>Anaheim, CA 92803                                      |            |



Addressee

Young D. Kim  
NWSC Code 3073  
Crane, Indiana 47522

Qty Addressee

Dr. Wendell Spence  
Nitron  
10420 Bubb Road  
Cupertino, CA 95014

Qty